TEXAS INSTRUMENTS
TPS7A83A
JAJSDB7B – JUNE 2017 – REVISED OCTOBER 2021

TPS7A83A 2A、高精度 (0.75%)、低ノイズ (4.4μV_{RMS}) LDO レギュレータ

1 特長

- 低いドロップアウト:200mV (最大値)、2A 時
- ライン、負荷、温度範囲にわたる精度 (BIAS あり): 0.75% (最大値)
- 出力電圧ノイズ:
  - 0.8V 出力で 4.4μV_{RMS}
- 入力電圧範囲:
  - BIAS なし:1.4V～6.5V
  - BIAS あり:1.1V～6.5V
- TPS7A8300A の出力電圧範囲:
  - 可変動作:0.8V～5.2V
  - ANY-OUT™ 動作:0.8V～3.95V
- TPS7A8301A の出力電圧範囲:
  - 可変動作:0.5V～5.2V
  - ANY-OUT™ 動作:0.5V～2.075V
- 電源リップル除去:
  - 500kHz 時 40dB
- 非常に優れた負荷過渡応答
- 調整可能なソフトスタート突入電流制御
- オープン・ドレインのパワー・グッド (PG) 出力

2 アプリケーション

- マクロ・リモート無線ユニット (RRU)
- 屋外バックホール・ユニット
- アクティブ・アンテナ・システム (AAS) の mMIMO
- 超音波スキャナ
- 実験室およびフィールド計測
- センサ、画像処理、レーダー

3 概要

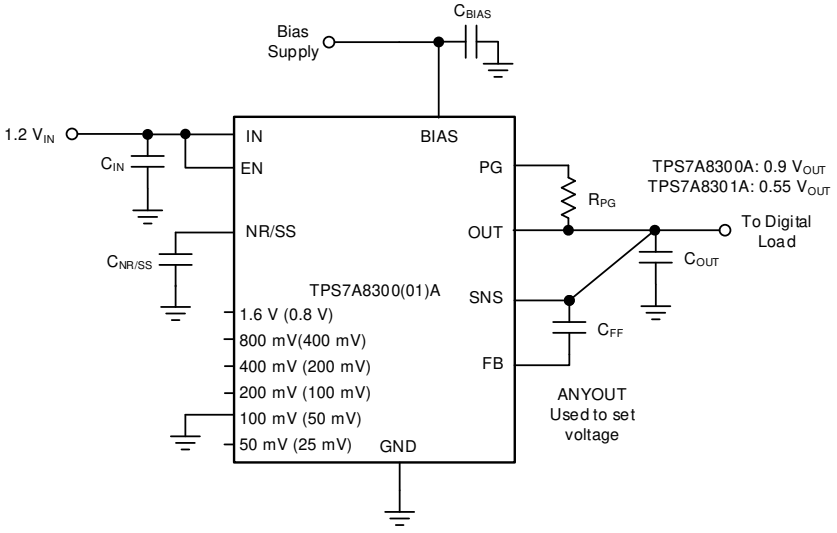
TPS7A83A は低ノイズ (4.4μV_{RMS})、低ドロップアウトのリニア・レギュレータ (LDO) で、2A を供給でき、ドロップアウトは最大でわずか 200 mV です。TPS7A8300A の出力電圧は、0.8V～3.95V の範囲を 50mV 刻みでピンによりプログラムでき、外付けの分圧抵抗を使用すると 0.8V～5.2V に調整できます。TPS7A8301A の出力電圧は、0.5V～2.075V の範囲を 25mV 刻みでピンによりプログラムでき、外付けの分圧抵抗を使用すると 0.5V～5.2V に調整できます。

TPS7A83A は、低ノイズ、高 PSRR、大出力電流という特性により、高速通信、ビデオ、医療機器、検査、計測などのアプリケーションで使用されるノイズに敏感な部品への電源供給に最適です。TPS7A83A の高い性能により、電源で発生する位相ノイズやクロック・ジッタが制限されるため、このデバイスは、高性能のシリアライザ / デシリアライザ (SerDes)、A/D コンバータ (ADC)、D/A コンバータ (DAC)、RF コンポーネントの電源に適しています。特に、RF アンプにはこのデバイスの高い性能と 5.2V 出力能力が役立ちます。

製品情報(1)

部品番号	パッケージ	本体サイズ (公称)
TPS7A83A	VQFN (20)	3.50mm × 3.50mm
		5.00mm × 5.00mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。



代表的なアプリケーション回路

英語版の TI 製品についての情報を翻訳したこの資料は、製品の概要を確認する目的で便宜的に提供しているものです。該当する正式な英語版の最新情報は、www.ti.com で閲覧でき、その内容が常に優先されます。TI では翻訳の正確性および妥当性につきましては一切保証いたしません。実際の設計などの前には、必ず最新版の英語版をご参照くださいますようお願いいたします。

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4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision A (November 2017) to Revision B (October 2021) — **Page**

- 文書全体にわたって表と図の採番方法を更新 ... 1
- ドキュメントに TPS7A8301A を追加 ... 1
- 「*特長*」セクションを変更 ... 1

Changes from Revision * (June 2017) to Revision A (November 2017) — **Page**

- ドキュメントに RGW パッケージを追加 ... 1
- 「特長」のパッケージ箇条書き項目に RGW パッケージを区別して追加 ... 1
- 「*アプリケーション*」セクションを変更 ... 1
- 「*概要*」セクションを変更 ... 1
- Added RGW thermal data to *Thermal Information* table ... 6
- Added *Typical Characteristics: TPS7A8301A* section ... 17

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5 概要 (続き)

デジタル負荷 (たとえば、ASIC (Application-Specific Integrated Circuit)、FPGA (Field-Programmable Gate Array)、DSP (Digital Signal Processor) など) で低入力電圧、低出力電圧 (LILO) 動作を必要とする場合には、TPS7A83A の非常に優れた精度 (負荷および温度範囲にわたって 0.75%)、リモート・センシング、優れた過渡性能、ソフトスタート機能によって、最適なシステム性能が確保されます。

多用途な TPS7A83A は、要求の厳しいさまざまなアプリケーションの部品として最適な選択肢です。

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6 Pin Configuration and Functions

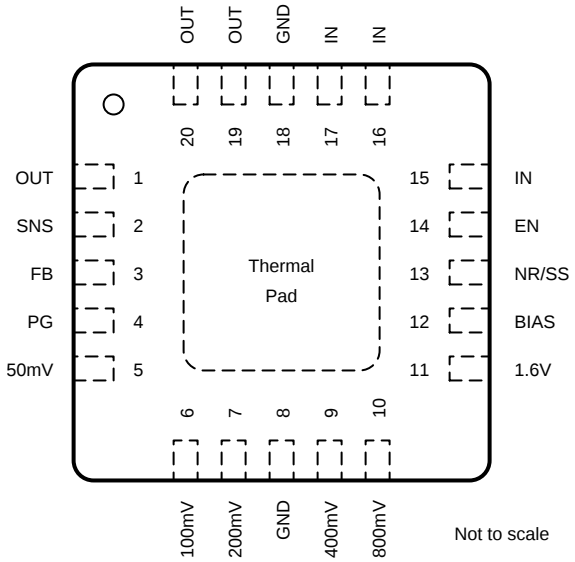


図 6-1. TPS7A8300A RGW and RGR Package, 20-Pin VQFN (Top View)

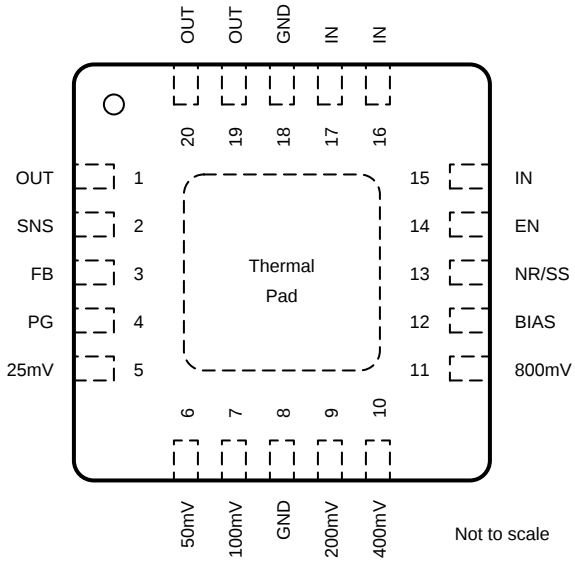


図 6-2. TPS7A8301A RGW and RGR Package, 20-Pin VQFN (Top View)

表 6-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME	TPS7A8300A	TPS7A8301A		
25mV	—	5	I	ANY-OUT voltage setting pins. These pins connect to an internal feedback network. Connect these pins to ground, SNS, or leave floating. Connecting these pins to ground increases the output voltage, whereas connecting these pins to SNS increases the resolution of the ANY-OUT network but decreases the range of the network; multiple pins can be simultaneously connected to GND or SNS to select the desired output voltage. Leave these pins floating (open) when not in use; see the *ANY-OUT Programmable Output Voltage* section for additional details.
50mV	5	6		
100mV	6	7		
200mV	7	9		
400mV	9	10		
800mV	10	11		
1.6V	11	—		
BIAS	12	12	I	BIAS supply voltage. This pin enables the use of low-input voltage, low-output (LILO) voltage conditions (that is, V_{IN} = 1.2 V, V_{OUT} = 1 V) to reduce power dissipation across the die. The use of a BIAS voltage improves dc and ac performance for $V_{IN} \leq$ 2.2 V. A 1-µF capacitor (0.47-µF capacitance) or larger must be connected between this pin and ground. If not used, this pin must be left floating or tied to ground.
EN	14	14	I	Enable pin. Driving this pin to logic high enables the device; driving this pin to logic low disables the device. If enable functionality is not required, this pin must be connected to IN or BIAS.
FB	3	3	I	Feedback pin connected to the error amplifier. Although not required, placing a 10-nF feed-forward capacitor from FB to OUT (as close to the device as possible) maximizes ac performance. Using a feed-forward capacitor may disrupt power-good (PG) functionality; see the *ANY-OUT Programmable Output Voltage* and *Adjustable Operation* sections for more details.
GND	8, 18	8, 18	—	Ground pin. These pins must be connected to ground, the thermal pad, and each other with a low-impedance connection.
IN	15-17	15-17	I	Input supply voltage pin. A 10-µF or larger ceramic capacitor (5 µF of capacitance or greater) from IN to ground is required to reduce the impedance of the input supply. Place the input capacitor as close as possible to the input; see the *Input and Output Capacitor Requirements (C_{IN} and C_{OUT})* section for more details.

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表 6-1. Pin Functions (continued)

PIN			I/O	DESCRIPTION
NAME	TPS7A8300A	TPS7A8301A		
NR/SS	13	13	—	Noise-reduction and soft-start pin. Connecting an external capacitor between this pin and ground reduces reference voltage noise and also enables the soft-start function. Although not required, connecting a 10-nF or larger capacitor from NR/SS to GND (as close as possible to the pin) maximizes ac performance; see the *Input and Output Capacitor Requirements (C_{IN} and C_{OUT})* section for more details.
OUT	1, 19, 20	1, 19, 20	O	Regulated output pin. A 47-µF or larger ceramic capacitor (25 µF of capacitance or greater) from OUT to ground is required for stability and must be placed as close as possible to the output. Minimize the impedance from the OUT pin to the load; see the *Input and Output Capacitor Requirements (C_{IN} and C_{OUT})* section for more details.
PG	4	4	O	Active-high, PG pin. An open-drain output indicates when the output voltage reaches $V_{IT(PG)}$ of the target. Using a feed-forward capacitor may disrupt PG functionality; see the *Input and Output Capacitor Requirements (C_{IN} and C_{OUT})* section for more details.
SNS	2	2	I	Output voltage sense input pin. This pin connects the internal R_1 resistor to the output. Connect this pin to the load side of the output trace only if the ANY-OUT feature is used. If the ANY-OUT feature is not used, leave this pin floating; see the *ANY-OUT Programmable Output Voltage* and *Adjustable Operation* sections for more details.
Thermal pad			—	Connect the thermal pad to a large-area ground plane. The thermal pad is internally connected to GND.

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7 Specifications

7.1 Absolute Maximum Ratings

over junction temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Voltage	IN, BIAS, PG, EN	–0.3	7.0	V
	IN, BIAS, PG, EN (5% duty cycle, pulse duration = 200 µs)	–0.3	7.5	
	SNS, OUT	–0.3	V_{IN} + 0.3(2)	
	NR/SS, FB	–0.3	3.6	
	50mV, 100mV, 200mV, 400mV, 800mV, 1.6V	–0.3	V_{OUT} + 0.3	
Current	OUT	Internally limited		A
	PG (sink current into device)		5	mA
Temperature	Operating junction, T_J	–55	150	°C
	Storage, T_{stg}	–55	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The absolute maximum rating is V_{IN} + 0.3 V or 7.0 V, whichever is smaller.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over junction temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input supply voltage range	1.1		6.5	V
V_{BIAS}	Bias supply voltage range(1)	3.0		6.5	V
V_{OUT}	Output voltage range (TPS7A8400A)(2)	0.8		5.2	V
	Output voltage range (TPS7A8401A)(2)	0.5		5.2	
V_{EN}	Enable voltage range	0		V_{IN}	V
I_{OUT}	Output current	0		2	A
C_{IN}	Input capacitor	10	22		µF
C_{OUT}	Output capacitor	22	22		µF
C_{BIAS}	Bias pin capacitor	1	10		µF
R_{PG}	Power-good pullup resistance	10		100	kΩ
$C_{NR/SS}$	NR/SS capacitor		10		nF
C_{FF}	Feed-forward capacitor		10		nF
R_1	Top resistor value in feedback network for adjustable operation		12.1(3)		kΩ
R_2	Bottom resistor value in feedback network for adjustable operation			160(4)	kΩ
T_J	Operating junction temperature	–40		125	°C

(1) BIAS supply is required when the V_{IN} supply is below 1.4 V. Conversely, no BIAS supply is required when the V_{IN} supply is higher than or equal to 1.4 V. A BIAS supply helps improve dc and ac performance for $V_{IN} \leq 2.2$ V.
(2) This output voltage range does not include device accuracy or accuracy of the feedback resistors.
(3) The 12.1-kΩ resistor is selected to optimize PSRR and noise by matching the internal R_1 value.
(4) The upper limit for the R_2 resistor is to ensure accuracy by making the current through the feedback network much larger than the leakage current into the feedback node.

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7.4 Thermal Information

THERMAL METRIC[1]		TPS7A83A		UNIT
		RGR (VQFN)	RGW (VQFN)	
		20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	43.4	33.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	36.8	24.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	17.6	13.0	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.8	0.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	17.6	13.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	3.4	3.9	°C/W

(1) For more information about traditional and new thermalmetrics, see the Semiconductor and ICPackage Thermal Metrics application report.

7.5 Electrical Characteristics: General

over operating junction temperature range (T_J = –40°C to +125°C), V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V for TPS7A8300A or 0.5 V for TPS7A8301A[1], OUT connected to 50 Ω to GND[2], V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, without C_{FF}, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted); typical values are at T_J = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{UVLO1(IN)}$	Input supply UVLO with BIAS	V_{IN} rising with V_{BIAS} = 3.0 V		1.02	1.085	V
$V_{HYS1(IN)}$	$V_{UVLO1(IN)}$ hysteresis	V_{BIAS} = 3.0 V		320		mV
$V_{UVLO2(IN)}$	Input supply UVLO without BIAS	V_{IN} rising		1.31	1.39	V
$V_{HYS2(IN)}$	$V_{UVLO2(IN)}$ hysteresis			253		mV
$V_{UVLO(BIAS)}$	Bias supply UVLO	V_{BIAS} rising, V_{IN} = 1.1 V		2.83	2.9	V
$V_{HYS(BIAS)}$	$V_{UVLO(BIAS)}$ hysteresis	V_{IN} = 1.1 V		290		mV
I_{EN}	EN pin current	V_{IN} = 6.5 V, V_{EN} = 0 V and 6.5 V	–0.1		0.1	µA
I_{BIAS}	BIAS pin current	V_{IN} = 1.1 V, V_{BIAS} = 6.5 V, $V_{OUT(nom)}$ = V_{OUT_MIN}, I_{OUT} = 2 A		2.3	3.5	mA
$V_{IL(EN)}$	EN pin low-level input voltage (disable device)		0		0.5	V
$V_{IH(EN)}$	EN pin high-level input voltage (enable device)		1.1		6.5	V
$V_{OL(PG)}$	PG pin low-level output voltage	V_{OUT} < $V_{IT(PG)}$, I_{PG} = –1 mA (current into device)			0.4	V
$I_{lkg(PG)}$	PG pin leakage current	V_{OUT} > $V_{IT(PG)}$, V_{PG} = 6.5 V			1	µA
$I_{NR/SS}$	NR/SS pin charging current	$V_{NR/SS}$ = GND, V_{IN} = 6.5 V	4.0	6.6	9.0	µA
I_{FB}	FB pin leakage current	V_{IN} = 6.5 V	–100		100	nA
T_{sd}	Thermal shutdown temperature	Shutdown, temperature increasing		160		°C
		Reset, temperature decreasing		140		
T_J	Operating junction temperature		–40		125	°C

(1) $V_{OUT(nom)}$ is the calculated V_{OUT} target value from the ANY-OUT in a fixed configuration. In an adjustable configuration, $V_{OUT(nom)}$ is the expected V_{OUT} value set by the external feedback resistors.
(2) This 50-Ω load is disconnected when the test conditions specify an I_{OUT} value.

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7.6 Electrical Characteristics: TPS7A8300A

over operating junction temperature range (T_J = –40°C to +125°C), V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V(1), OUT connected to 50 Ω to GND(2), V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 47 µF, $C_{NR/SS}$ =0 nF, without C_{FF}, and PG pin pulled up to V_{IN} with 100 kohm, unless otherwise noted; Typical values are at T_J = 25°C

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{FB}	Feedback voltage					0.8		V
$V_{NR/SS}$	NR/SS pin voltage					0.8		V
V_{OUT}	Output voltage	Range	Using the ANY-OUT pins		0.8 – 1.0%		3.95 + 1.0%	V
			Using external resistors(3)		0.8 – 1.0%		5.2 + 1.0%	
		Accuracy(3) (4)	0.8 V ≤ V_{OUT} ≤ 5.2(5) V, 5 mA ≤ I_{OUT} ≤ 2 A, over V_{IN}		–1.0%		1.0%	
		Accuracy with BIAS	1.1V ≤ V_{IN} ≤ 2.2 V, 5 mA ≤ I_{OUT} ≤ 2 A, 3.0 V ≤ V_{BIAS} ≤ 6.5 V		–0.75%		0.75%	
$\Delta V_{OUT}/\Delta V_{IN}$	Line regulation		I_{OUT} = 5 mA, 1.4 V ≤ V_{IN} ≤ 6.5 V			0.03		mV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation		5 mA ≤ I_{OUT} ≤ 2 A, 3.0 V ≤ V_{BIAS} ≤ 6.5 V, V_{IN} = 1.1 V			0.07		mV/A
			5 mA ≤ I_{OUT} ≤ 2 A			0.08		
			5 mA ≤ I_{OUT} ≤ 2 A, V_{OUT} = 5.15 V			0.04		
V_{DO}	Dropout voltage		V_{IN} = 1.4 V, I_{OUT} = 2 A, V_{FB} = 0.8 V – 3%				200	mV
			V_{IN} = 5.3 V, I_{OUT} = 2 A, V_{FB} = 0.8 V – 3%				200	
			V_{IN} = 5.5 V, I_{OUT} = 2 A, V_{FB} = 0.8 V – 3%				300	
			V_{IN} = 1.1 V, V_{BIAS} = 5 V, I_{OUT} = 2 A, V_{FB} = 0.8 V – 3%				125	
I_{LIM}	Output current limit		V_{OUT} forced at 0.9 × $V_{OUT(nom)}$, V_{IN} = $V_{OUT(nom)}$ + 0.4 V		2.8	3.3	3.8	A
I_{SC}	Short-circuit current limit		R_{LOAD} = 20 mΩ, under foldback operation			1.0		A
PSRR	Power-supply ripple rejection		V_{IN} – V_{OUT} = 0.4 V, I_{OUT} = 2 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 22 µF	f = 10 kHz, V_{OUT} = 0.8 V, V_{BIAS} = 5.0 V		42		dB
				f = 500 kHz, V_{OUT} = 0.8 V, V_{BIAS} = 5.0 V		39		
				f = 10 kHz, V_{OUT} = 5.0 V		40		
				f = 500 kHz, V_{OUT} = 5.0 V		25		
V_n	Output noise voltage		BW = 10 Hz to 100 kHz, V_{IN} = 1.1 V, V_{OUT} = 0.8 V, V_{BIAS} = 5.0 V, I_{OUT} = 2 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 22 µF			4.4		μV_{RMS}
			BW = 10 Hz to 100 kHz, V_{OUT} = 5.0 V, I_{OUT} = 2 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 22 µF			7.7		
I_{GND}	GND pin current		V_{IN} = 6.5 V, I_{OUT} = 5 mA			2.8	4	mA
			V_{IN} = 1.4 V, I_{OUT} = 2 A			3.7	5	
			Shutdown, PG = open, V_{IN} = 6.5 V, V_{EN} = 0.5 V			1.2	25	µA
V_{IT}(PG)	PG pin threshold		For falling V_{OUT}		82% . V_{OUT}	88% . V_{OUT}	93% . V_{OUT}	V
V_{HYS}(PG)	PG pin hysteresis		For rising V_{OUT}			2% . V_{OUT}		V

(1) $V_{OUT(nom)}$ is the calculated V_{OUT} target value from the ANY-OUT in a fixed configuration. In an adjustable configuration, $V_{OUT(nom)}$ is the expected V_{OUT} value set by the external feedback resistors.
(2) This 50-Ω load is disconnected when the test conditions specify an I_{OUT} value.
(3) When the device is connected to external feedback resistors at the FB pin, external resistor tolerances are not included.
(4) The device is not tested under conditions where V_{IN} > V_{OUT} + 1.7 V and I_{OUT} = 3 A, because the power dissipation is higher than the maximum rating of the package.
(5) For V_{OUT} ≤ 5 V, V_{IN} = V_{OUT} + 0.4 V; for V_{OUT} > 5 V, V_{IN} = V_{OUT} + 0.45 V.

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7.7 Electrical Characteristics: TPS7A8301A

over operating junction temperature range (T_J = –40°C to +125°C), V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.4 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.5 V(1), OUT connected to 50 Ω to GND(2), V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 47 µF, $C_{NR/SS}$ = 0 nF, without C_{FF}, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted); typical values are at T_J = 25°C

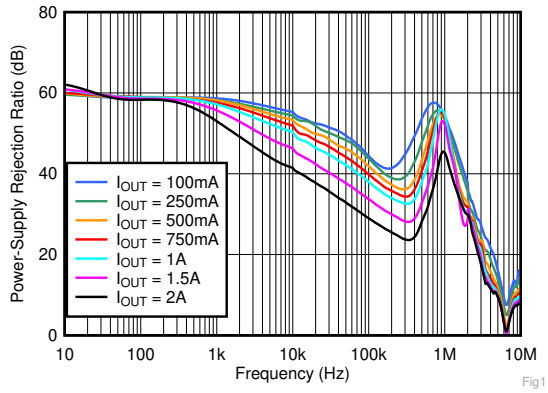
PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{FB}	Feedback voltage					0.5		V
$V_{NR/SS}$	NR/SS pin voltage					0.5		V
V_{OUT}	Output voltage	Range	Using the ANY-OUT pins		0.5 – 1.2%		2.075 + 1.0%	V
			Using external resistors(3)		0.5 – 1.2%		5.2 + 1.0%	
		Accuracy(3) (4)	0.5 V ≤ V_{OUT} ≤ 5.2(5) V, 5 mA ≤ I_{OUT} ≤ 2 A, over V_{IN}		–1.25%		1.25%	
		Accuracy with BIAS	V_{IN} = 1.1 V, V_{OUT} = 0.5 V, 5 mA ≤ I_{OUT} ≤ 2 A, 3.0 V ≤ V_{BIAS} ≤ 6.5 V		–1.0%		1.1%	
$\Delta V_{OUT}/\Delta V_{IN}$	Line regulation		I_{OUT} = 5 mA, 1.4 V ≤ V_{IN} ≤ 6.5 V			0.03		mV/V
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation		5 mA ≤ I_{OUT} ≤ 2 A, 3.0 V ≤ V_{BIAS} ≤ 6.5 V, V_{IN} = 1.1 V			0.07		mV/A
			5 mA ≤ I_{OUT} ≤ 2 A			0.08		
			5 mA ≤ I_{OUT} ≤ 2 A, V_{OUT} = 5.2 V			0.04		
V_{DO}	Dropout voltage		V_{IN} = 1.4 V, I_{OUT} = 2 A, V_{FB} = 0.5 V – 3%				210	mV
			V_{IN} = 5.3 V, I_{OUT} = 2 A, V_{FB} = 0.5 V – 3%				215	
			V_{IN} = 5.5 V, I_{OUT} = 2 A, V_{FB} = 0.5 V – 3%				300	
			V_{IN} = 1.1 V, V_{BIAS} = 5 V, I_{OUT} = 2 A, V_{FB} = 0.5 V – 3%				125	
I_{LIM}	Output current limit		V_{OUT} forced at 0.9 × $V_{OUT(nom)}$, V_{IN} = $V_{OUT(nom)}$ + 0.4 V		2.8	3.3	3.8	A
I_{SC}	Short-circuit current limit		R_{LOAD} = 20 mΩ, under foldback operation			1		A
PSRR	Power-supply ripple rejection		V_{IN} – V_{OUT} = 0.4 V, I_{OUT} = 2 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 22 µF	f = 10 kHz, V_{OUT} = 0.5 V, V_{BIAS} = 5.0 V		42		dB
				f = 500 kHz, V_{OUT} = 0.5 V, V_{BIAS} = 5.0 V		39		
				f = 10 kHz, V_{OUT} = 5.0 V		40		
				f = 500 kHz, V_{OUT} = 5.0 V		25		
V_n	Output noise voltage		BW = 10 Hz to 100 kHz, V_{IN} = 1.1 V, V_{OUT} = 0.5 V, V_{BIAS} = 5.0 V, I_{OUT} = 2 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 22 µF			4.4		μV_{RMS}
			BW = 10 Hz to 100 kHz, V_{OUT} = 5.0 V, I_{OUT} = 2 A, $C_{NR/SS}$ = 100 nF, C_{FF} = 10 nF, C_{OUT} = 22 µF			7.7		
I_{GND}	GND pin current		V_{IN} = 6.5 V, I_{OUT} = 5 mA			2.3	4.3	mA
			V_{IN} = 1.4 V, I_{OUT} = 2 A			3.7	5	
			Shutdown, PG = open, V_{IN} = 6.5 V, V_{EN} = 0.5 V			1.2	25	µA
$V_{IT(PG)}$	PG pin threshold		For falling V_{OUT}		80% . V_{OUT}	86% . V_{OUT}	91% . V_{OUT}	V
$V_{HYS(PG)}$	PG pin hysteresis		For rising V_{OUT}			5% . V_{OUT}		V

(1) $V_{OUT(nom)}$ is the calculated V_{OUT} target value from the ANY-OUT in a fixed configuration. In an adjustable configuration, $V_{OUT(nom)}$ is the expected V_{OUT} value set by the external feedback resistors.
(2) This 50-Ω load is disconnected when the test conditions specify an I_{OUT} value.
(3) When the device is connected to external feedback resistors at the FB pin, external resistor tolerances are not included.
(4) The device is not tested under conditions where V_{IN} > V_{OUT} + 1.7 V and I_{OUT} = 3 A, because the power dissipation is higher than the maximum rating of the package.
(5) For V_{OUT} ≤ 5 V, V_{IN} = V_{OUT} + 0.4 V; for V_{OUT} > 5 V, V_{IN} = V_{OUT} + 0.45 V.

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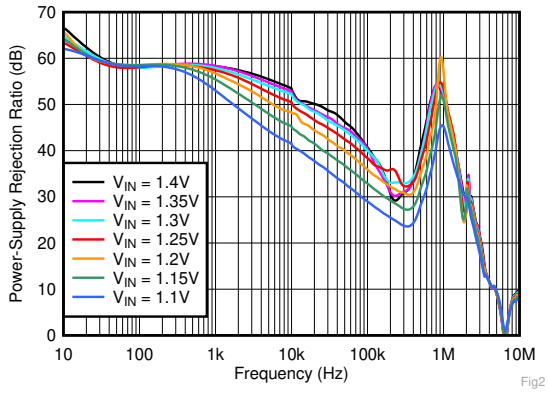
7.8 Typical Characteristics: TPS7A8300A

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



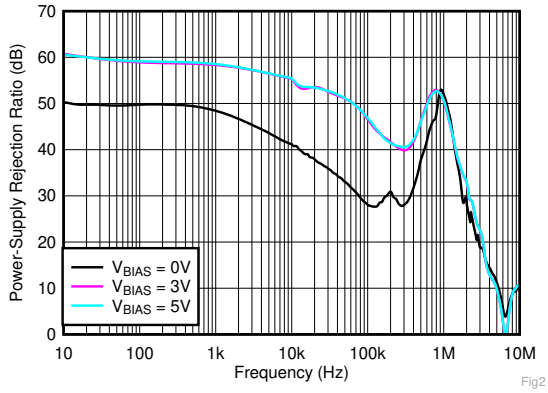
V_{IN} = 1.1 V, V_{BIAS} = 5 V, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-1. PSRR vs Frequency and I_{OUT}



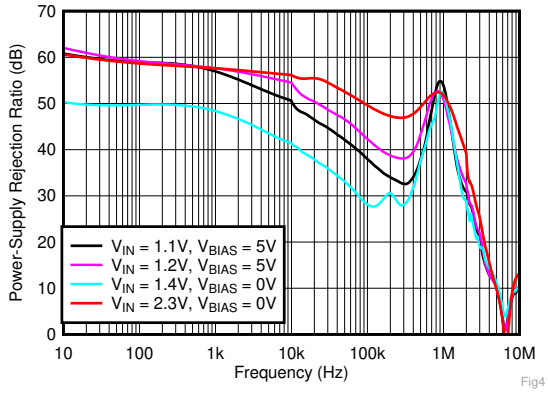
I_{OUT} = 2 A, V_{BIAS} = 5 V, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-2. PSRR vs Frequency and V_{IN} With BIAS



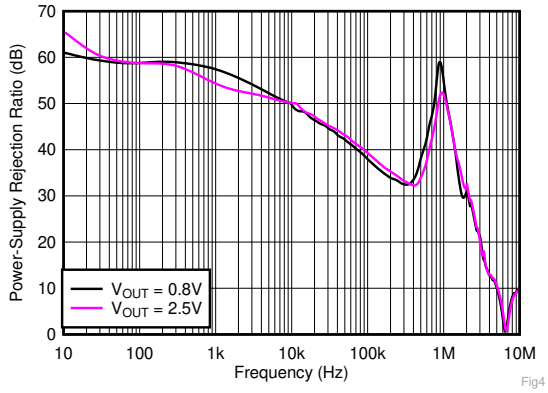
V_{IN} = 1.4 V, I_{OUT} = 1 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-3. PSRR vs Frequency and V_{BIAS}



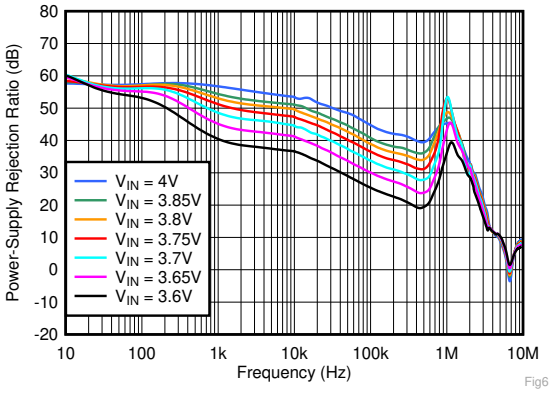
I_{OUT} = 1 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-4. PSRR vs Frequency and V_{IN}



V_{IN} = V_{OUT} + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 2 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-5. PSRR vs Frequency and V_{OUT} With BIAS



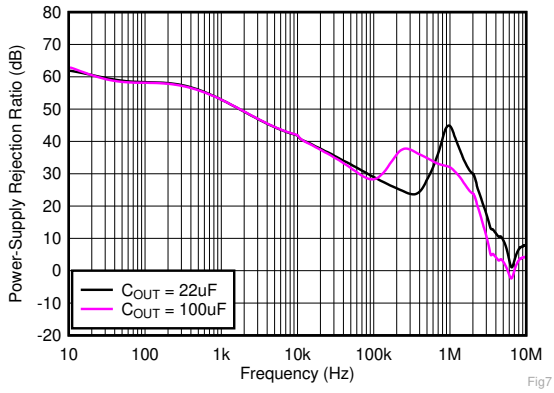
I_{OUT} = 2 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-6. PSRR vs Frequency and V_{IN} for V_{OUT} = 3.3 V

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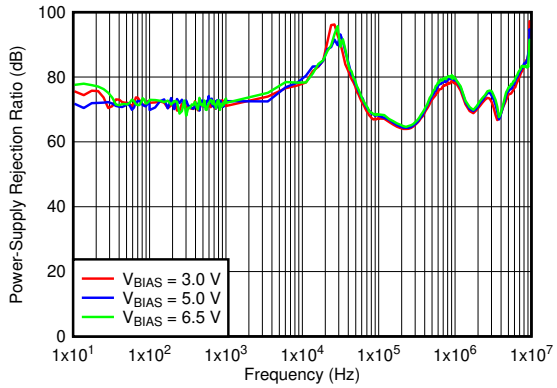
7.8 Typical Characteristics: TPS7A8300A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



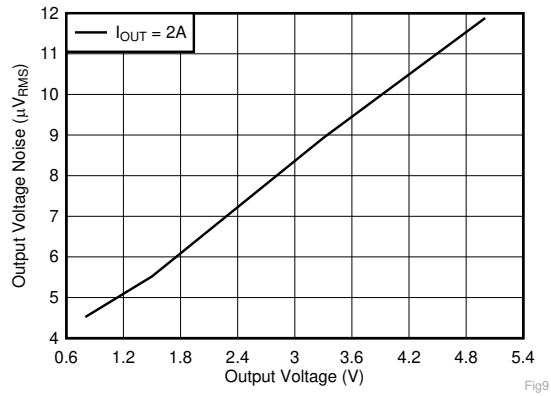
V_{IN} = V_{OUT} + 0.3 V, V_{OUT} = 1 V, V_{BIAS} = 5 V, I_{OUT} = 2 A, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-7. PSRR vs Frequency and C_{OUT}



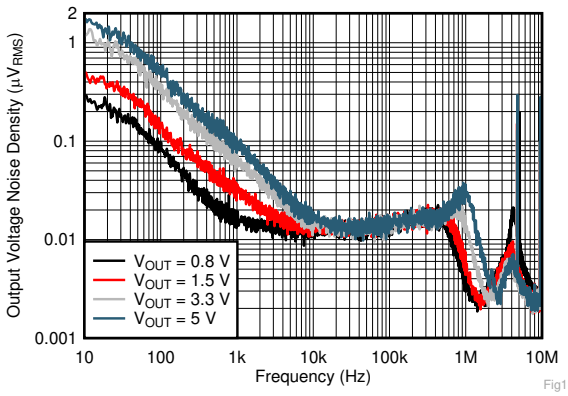
V_{IN} = V_{OUT} + 0.3 V, V_{OUT} = 1 V, I_{OUT} = 2 A, C_{OUT} = 47 µF || 10 µF || 10 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-8. V_{BIAS} PSRR vs Frequency



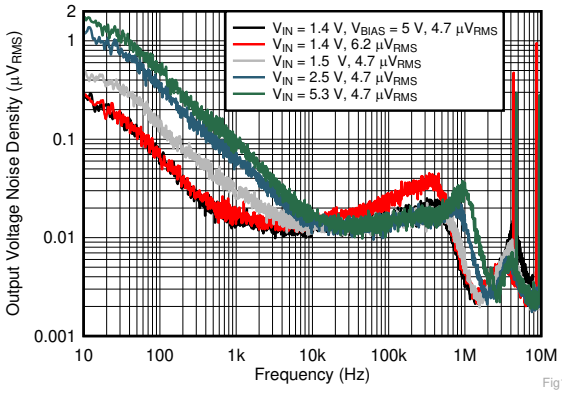
V_{IN} = V_{OUT} + 0.3 V and V_{BIAS} = 5 V for V_{OUT} ≤ 2.2 V, C_{OUT} = 22 µF, C_{BIAS} = 10 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

図 7-9. Output Voltage Noise vs Output Voltage



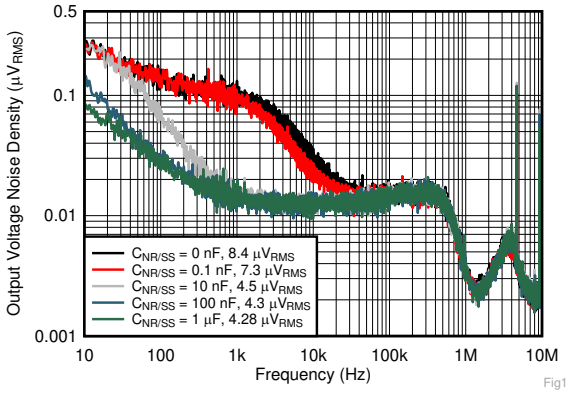
V_{IN} = V_{OUT} + 0.3 V and V_{BIAS} = 5 V for V_{OUT} ≤ 2.2 V, I_{OUT} = 2 A, C_{OUT} = 22 µF, C_{BIAS} = 10 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

図 7-10. Output Noise vs Frequency and Output Voltage



I_{OUT} = 2 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

図 7-11. Output Noise vs Frequency and Input Voltage



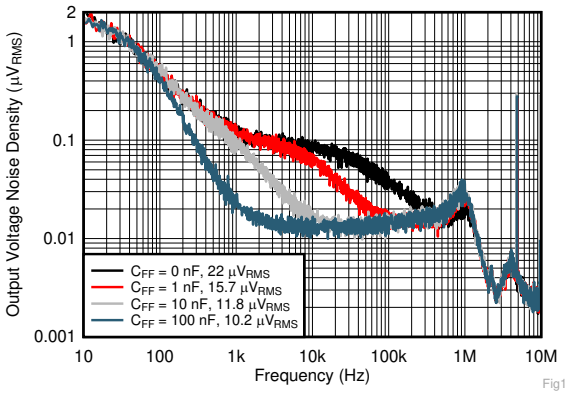
V_{IN} = 1.1 V, V_{OUT} = 0.8 V, V_{BIAS} = 5 V, I_{OUT} = 2 A, C_{OUT} = 22 µF, C_{BIAS} = 10 µF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

図 7-12. Output Noise vs Frequency and $C_{NR/SS}$

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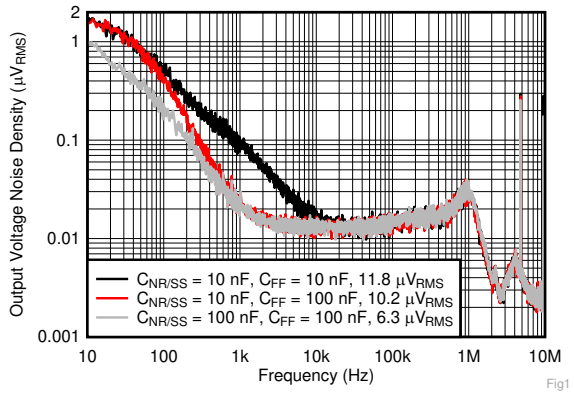
7.8 Typical Characteristics: TPS7A8300A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



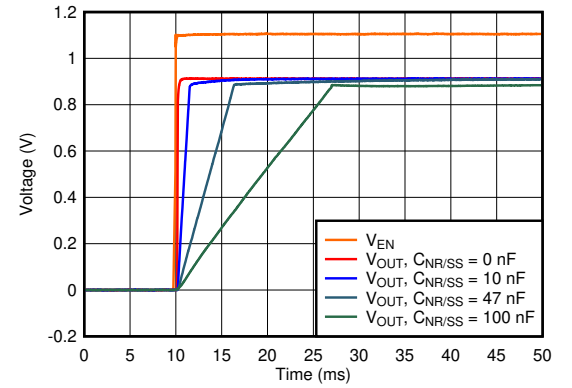
V_{IN} = 5.3 V, V_{OUT} = 5 V, V_{BIAS} = 5 V, I_{OUT} = 2 A, C_{OUT} = 22 µF, C_{BIAS} = 10 µF, $C_{NR/SS}$ = 10 nF, RMS noise BW = 10 Hz to 100 kHz

図 7-13. Output Noise vs Frequency and C_{FF}



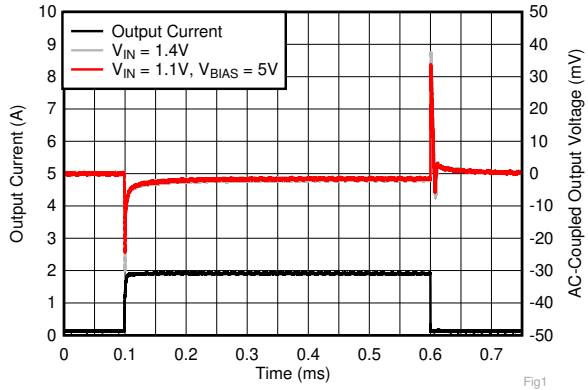
I_{OUT} = 2 A, C_{OUT} = 22 µF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

図 7-14. Output Noise at 5-V Output



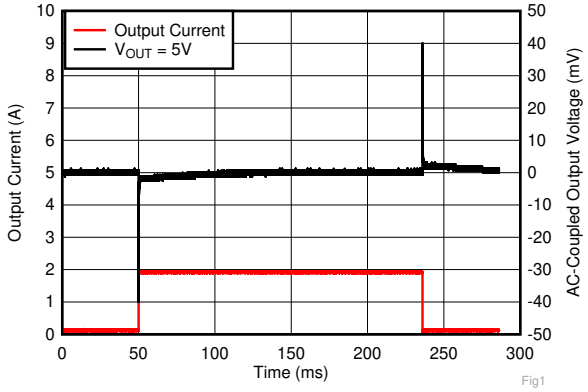
V_{IN} = 1.2 V, V_{OUT} = 0.9 V, V_{BIAS} = 5 V, I_{OUT} = 2 A, C_{OUT} = 22 µF, C_{BIAS} = 10 µF, C_{FF} = 10 nF

図 7-15. Start-Up Waveform vs Time and $C_{NR/SS}$



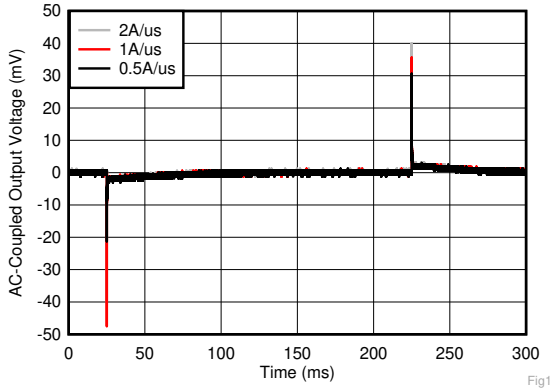
$I_{OUT, DC}$ = 100 mA, slew rate = 1 A/µs, $C_{NR/SS}$ = 10 nF, C_{OUT} = 22 µF, C_{BIAS} = 10 µF

図 7-16. Load Transient vs Time for V_{OUT} = 0.8 V



$I_{OUT, DC}$ = 100 mA, C_{OUT} = 22 µF, $C_{NR/SS}$ = C_{FF} = 10 nF, slew rate = 1 A/µs

図 7-17. Load Transient vs Time for V_{OUT} = 5 V



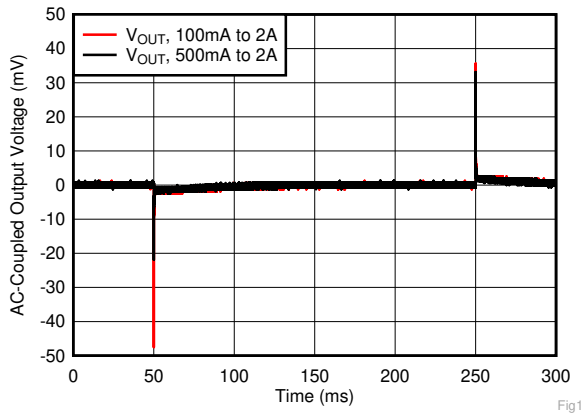
V_{OUT} = 5 V, $I_{OUT, DC}$ = 100 mA, I_{OUT} = 100 mA to 2 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = C_{FF} = 10 nF

図 7-18. Load Transient vs Time and Slew Rate

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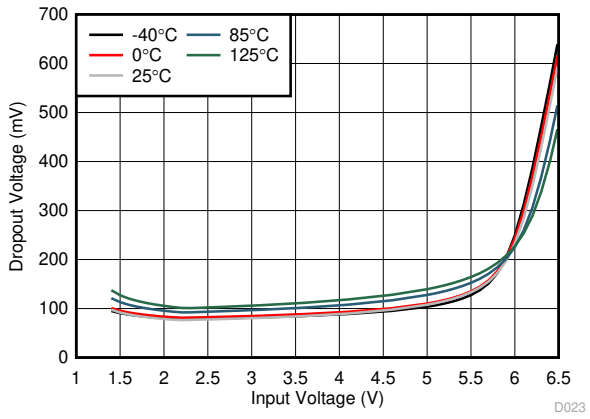
7.8 Typical Characteristics: TPS7A8300A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



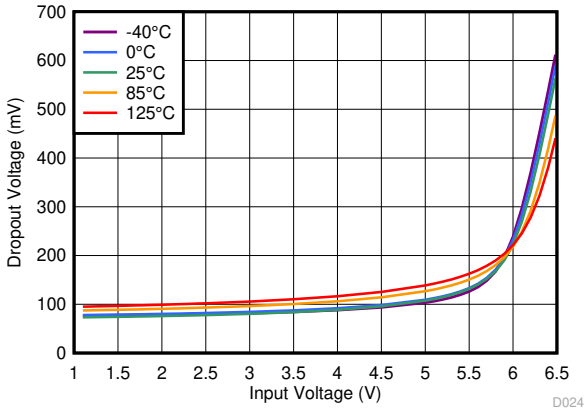
V_{IN} = 5.3 V, V_{BIAS} = 5 V, C_{OUT} = 22 µF, C_{BIAS} = 10 µF, V_{OUT} = 5 V, $C_{NR/SS}$ = C_{FF} = 10 nF, slew rate = 1 A/µs

図 7-19. Load Transient vs Time and DC Load



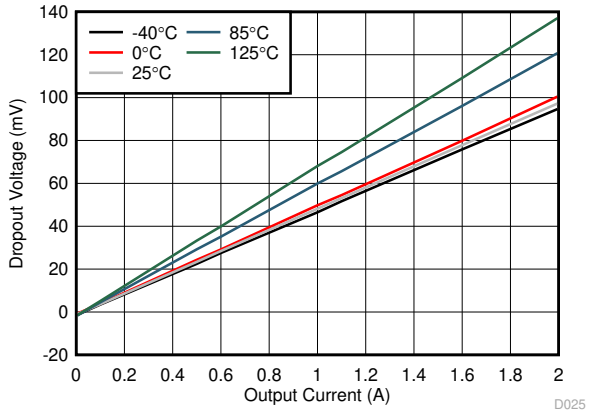
I_{OUT} = 2 A

図 7-20. Dropout Voltage vs Input Voltage Without BIAS



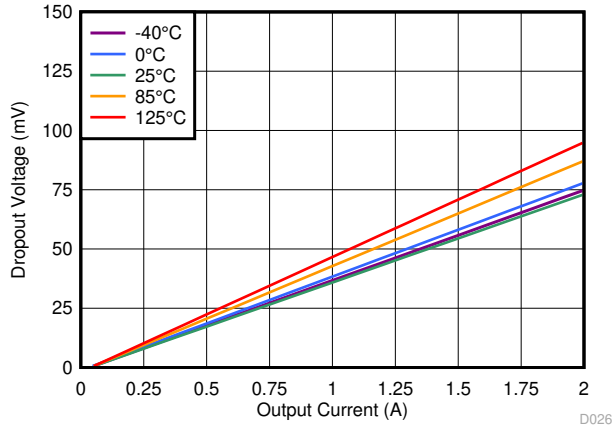
I_{OUT} = 2 A, V_{BIAS} = 6.5 V

図 7-21. Dropout Voltage vs Input Voltage With BIAS



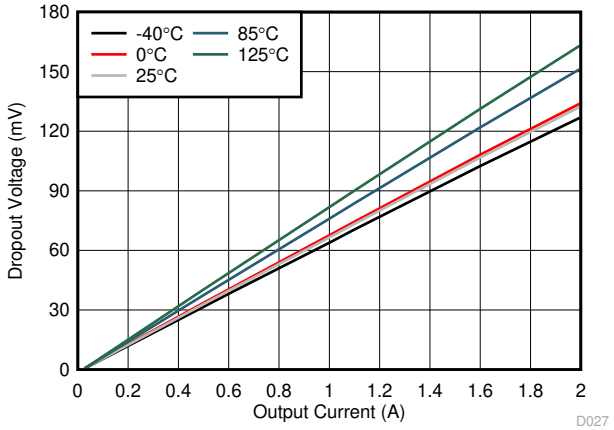
V_{IN} = 1.4 V

図 7-22. Dropout Voltage vs Output Current Without BIAS



V_{IN} = 1.1 V, V_{BIAS} = 3 V

図 7-23. Dropout Voltage vs Output Current With BIAS



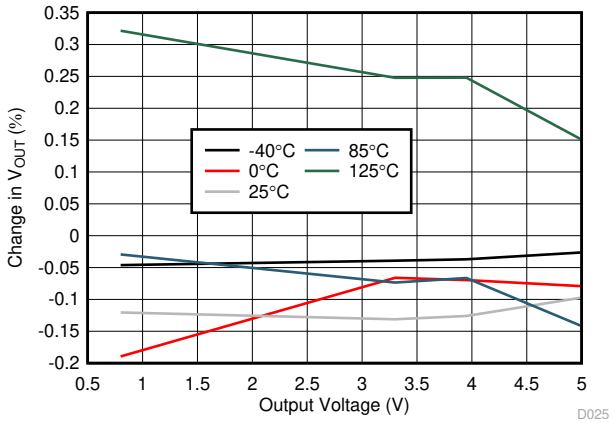
V_{IN} = 5.5 V

図 7-24. Dropout Voltage vs Output Current (High V_{IN})

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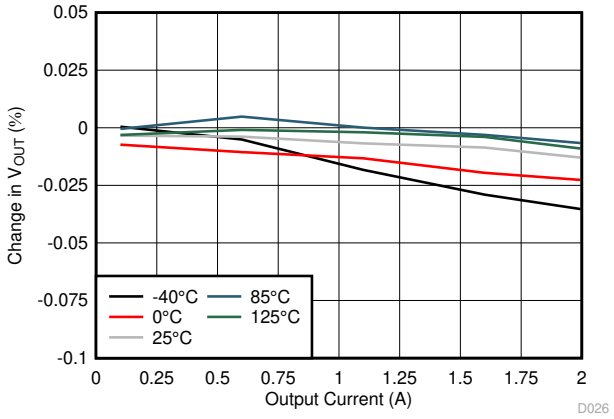
7.8 Typical Characteristics: TPS7A8300A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



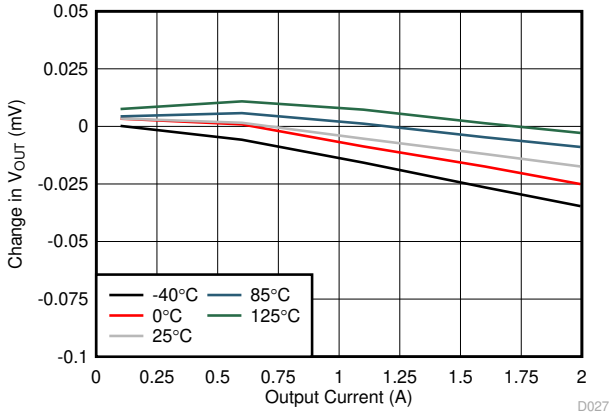
I_{OUT} = 100 mA to 2 A

図 7-25. Load Regulation vs Output Voltage



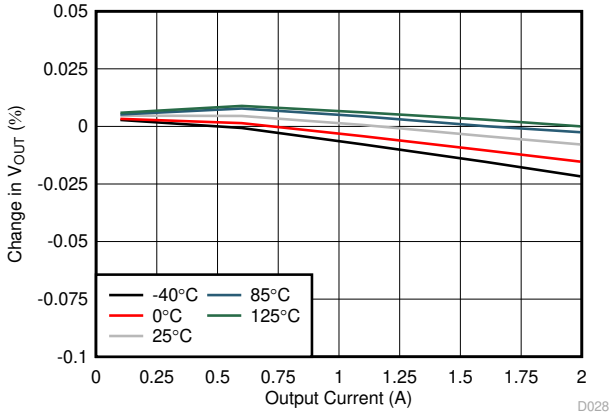
V_{IN} = 1.4 V

図 7-26. Load Regulation



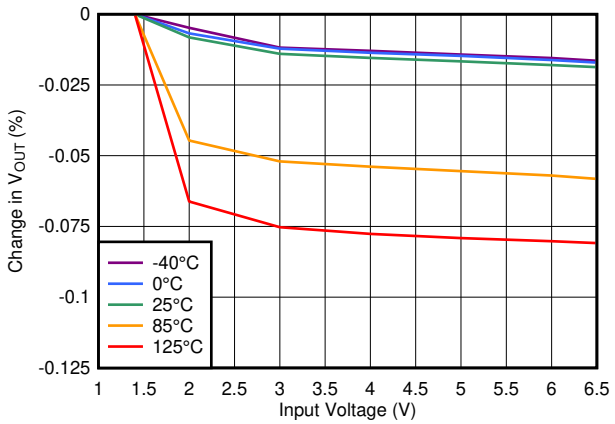
V_{IN} = 3.8 V

図 7-27. Load Regulation (3.3-V Output)



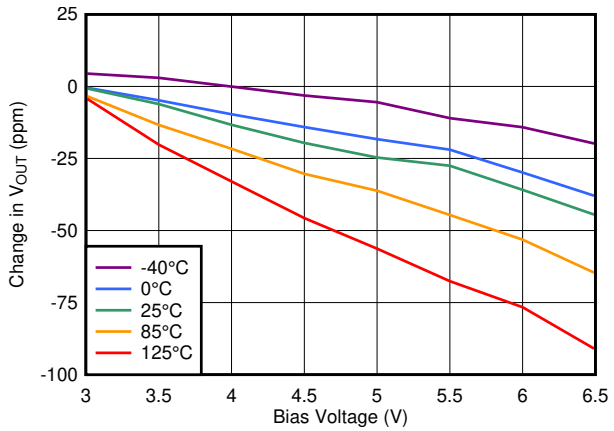
V_{IN} = 5.5 V

図 7-28. Load Regulation (5-V Output)



V_{OUT} = 0.8 V, I_{OUT} = 5 mA

図 7-29. Line Regulation



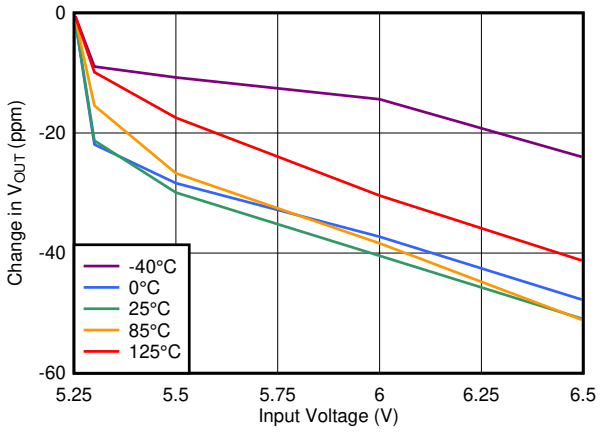
V_{OUT} = 0.8 V, V_{IN} = 1.1 V, I_{OUT} = 5 mA, V_{BIAS} = 5 V

図 7-30. Line Regulation With BIAS

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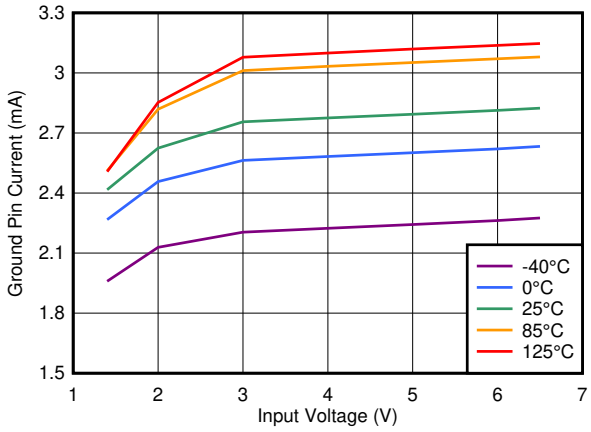
7.8 Typical Characteristics: TPS7A8300A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



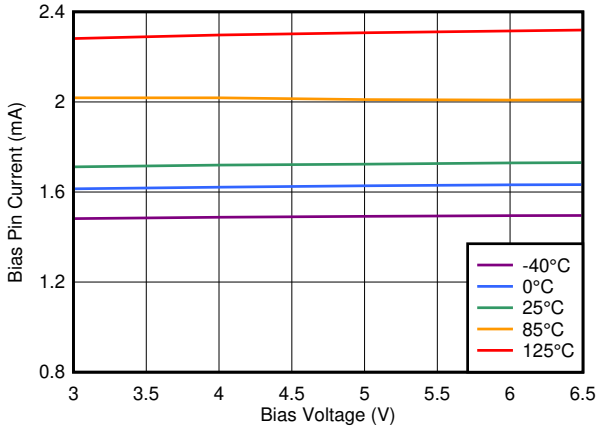
I_{OUT} = 5 mA

図 7-31. Line Regulation (5-V Output)



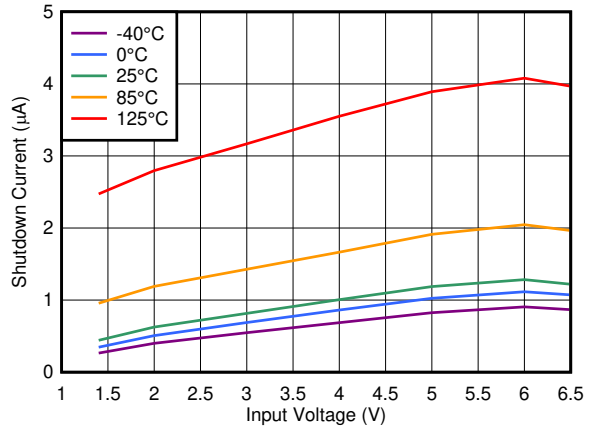
V_{BIAS} = 0 V, I_{OUT} = 5 mA

図 7-32. Ground Pin Current vs Input Voltage



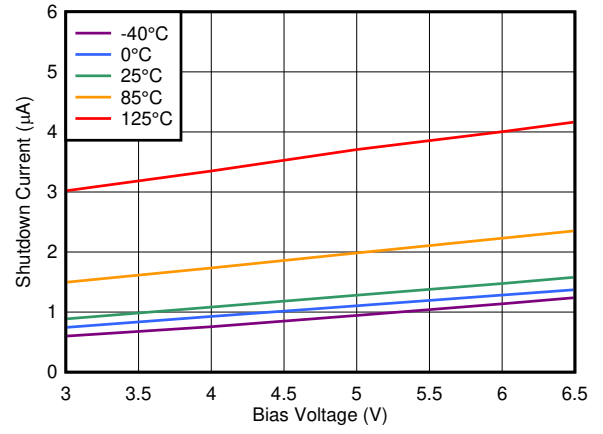
V_{IN} = 1.1 V, I_{OUT} = 5 mA

図 7-33. BIAS Pin Current vs Bias Voltage



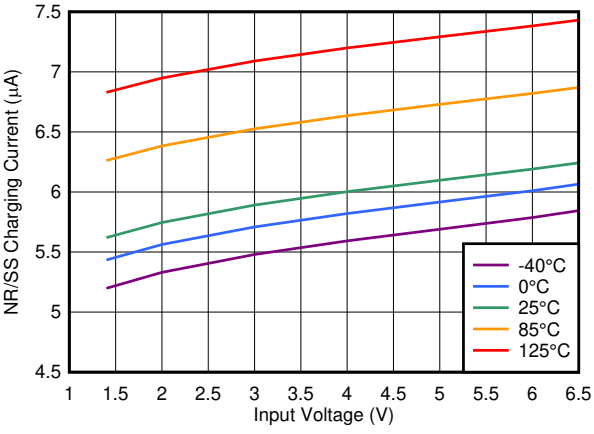
V_{BIAS} = 0 V

図 7-34. Shutdown Current vs Input Voltage



V_{IN} = 1.1 V

図 7-35. Shutdown Current vs Bias Voltage



V_{BIAS} = 0 V

図 7-36. $I_{NR/SS}$ Current vs Input Voltage

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7.8 Typical Characteristics: TPS7A8300A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)

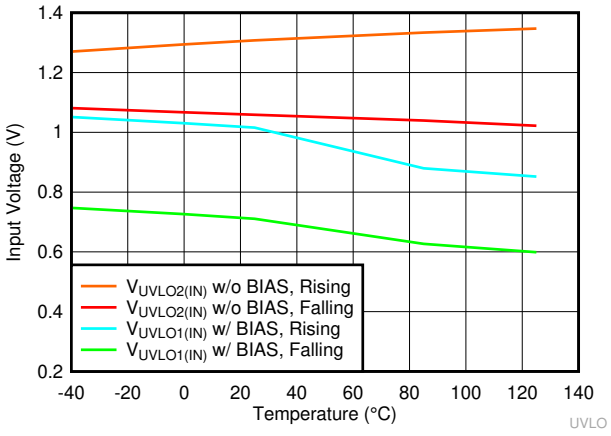


図 7-37. V_{IN} UVLO vs Temperature

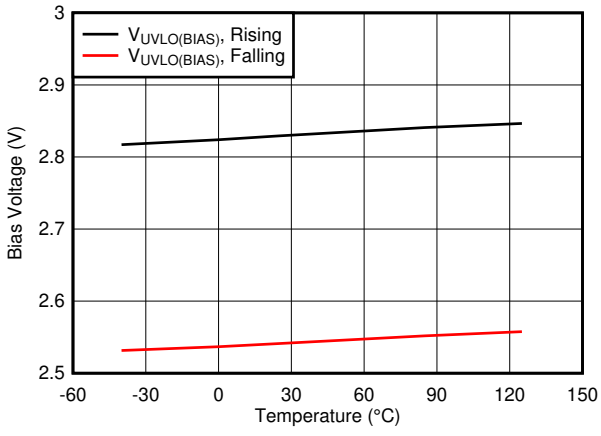


図 7-38. V_{BIAS} UVLO vs Temperature

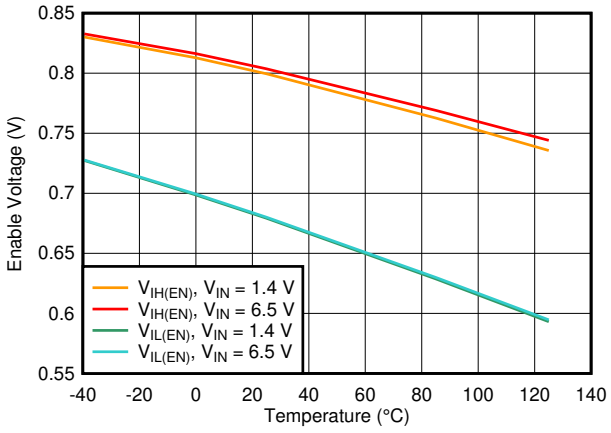


図 7-39. Enable Threshold vs Temperature

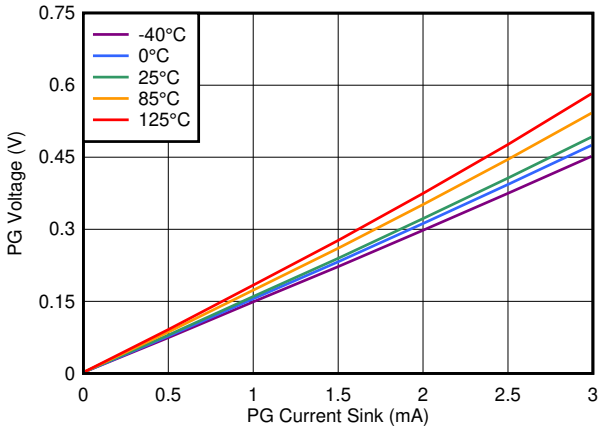


図 7-40. PG Voltage vs PG Current Sink

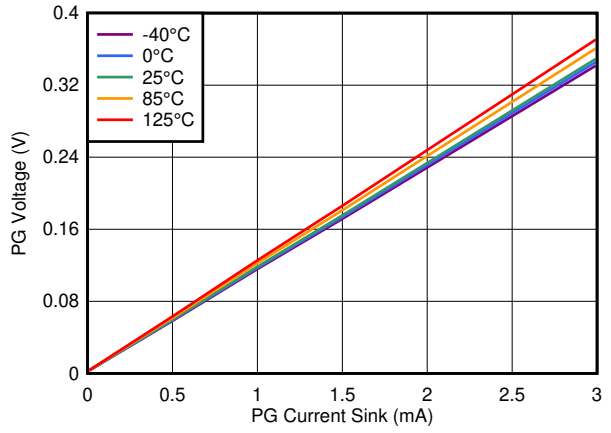


図 7-41. PG Voltage vs PG Current Sink

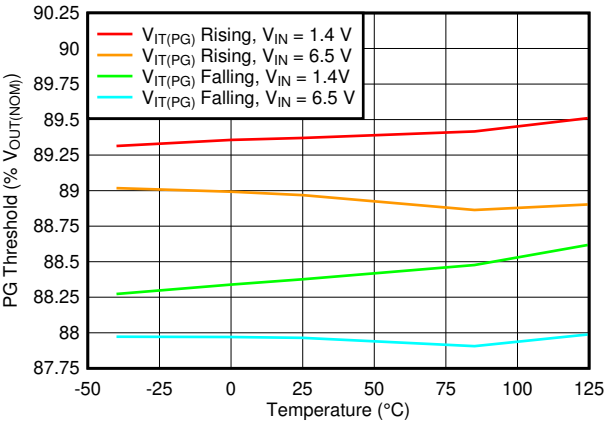
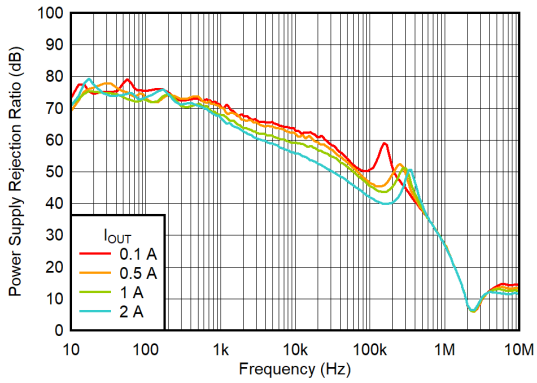


図 7-42. PG Threshold vs Temperature

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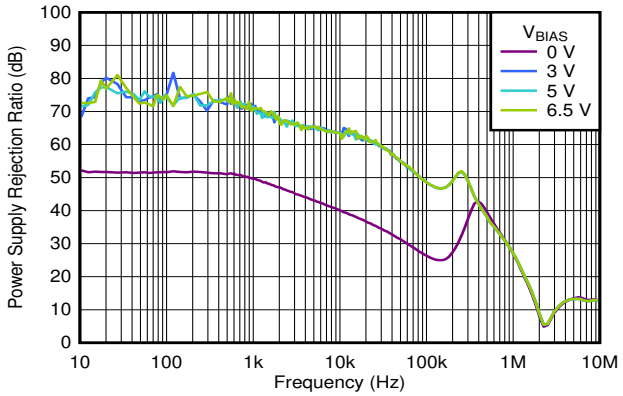
7.9 Typical Characteristics: TPS7A8301A

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



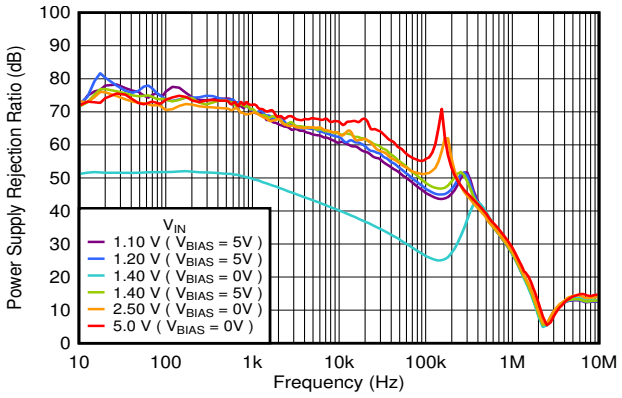
V_{IN} = 1.1 V, V_{BIAS} = 5 V, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-43. PSRR vs Frequency and I_{OUT}



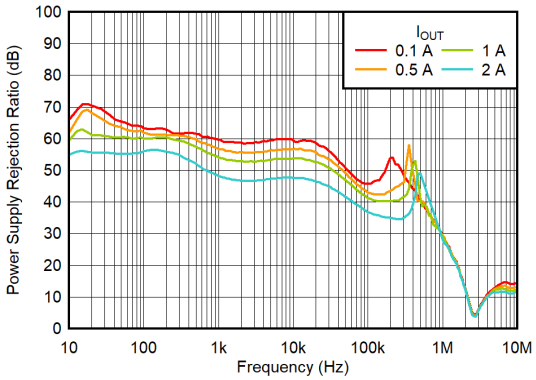
V_{IN} = 1.4 V, I_{OUT} = 1 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-44. PSRR vs Frequency and V_{BIAS}



I_{OUT} = 1 A, C_{OUT} = 22 µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-45. PSRR vs Frequency and V_{IN}



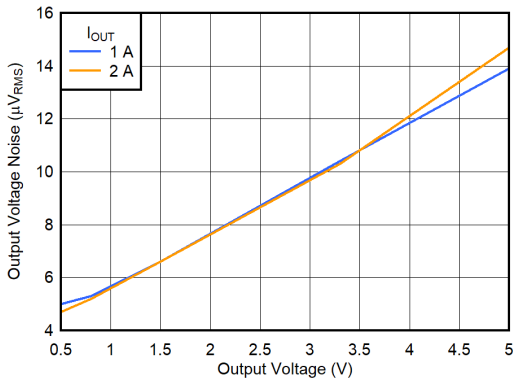
V_{IN} = 5.5 V, V_{OUT} = 5 V, C_{OUT} = 47 µF || 10 µF || 10µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF

図 7-46. PSRR vs Frequency and I_{OUT} (V_{OUT} = 5 V)

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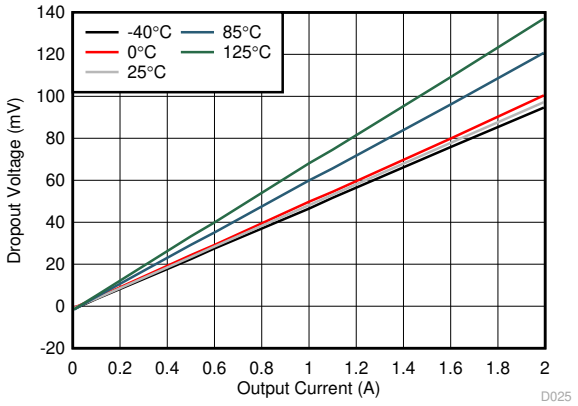
7.9 Typical Characteristics: TPS7A8301A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



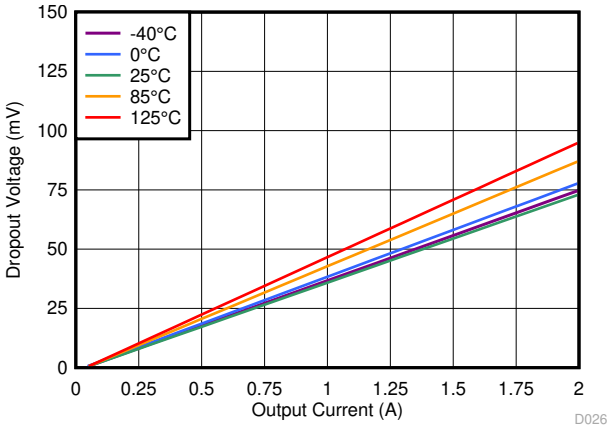
V_{IN} = V_{OUT} + 0.3 V or V_{IN} = 1.1 V (whichever is greater) and V_{BIAS} = 5 V for V_{OUT} ≤ 2.2 V, C_{OUT} = 47 µF || 10µF || 10µF, $C_{NR/SS}$ = 10 nF, C_{FF} = 10 nF, RMS noise BW = 10 Hz to 100 kHz

図 7-47. Output Voltage Noise vs V_{OUT}



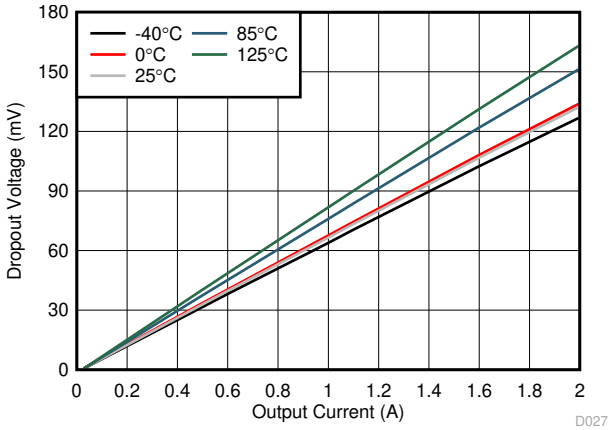
V_{IN} = 1.4 V

図 7-48. Dropout Voltage vs Output Current Without BIAS



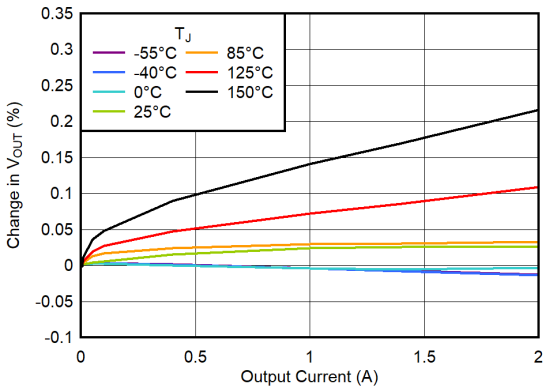
V_{IN} = 1.1 V, V_{BIAS} = 3 V

図 7-49. Dropout Voltage vs Output Current With BIAS



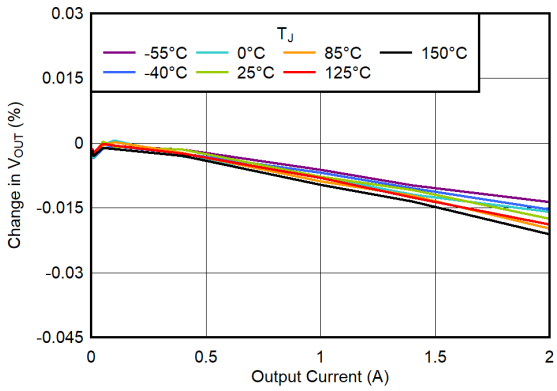
V_{IN} = 5.5 V

図 7-50. Dropout Voltage vs Output Current (High V_{IN})



V_{IN} = 1.4 V

図 7-51. Load Regulation



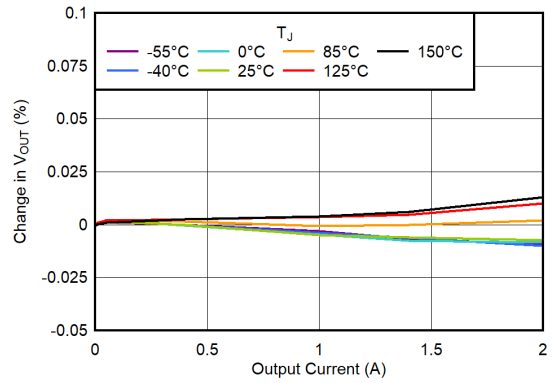
V_{IN} = 3.8 V

図 7-52. Load Regulation (3.3-V Output)

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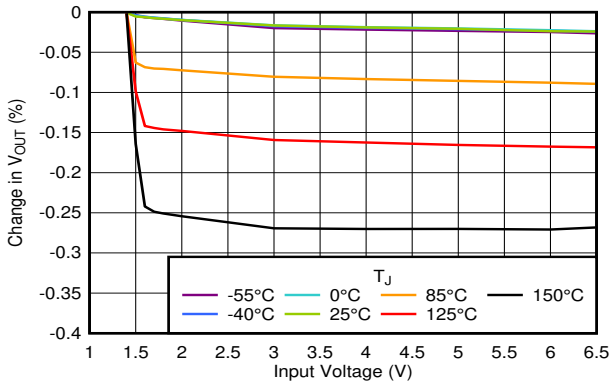
7.9 Typical Characteristics: TPS7A8301A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



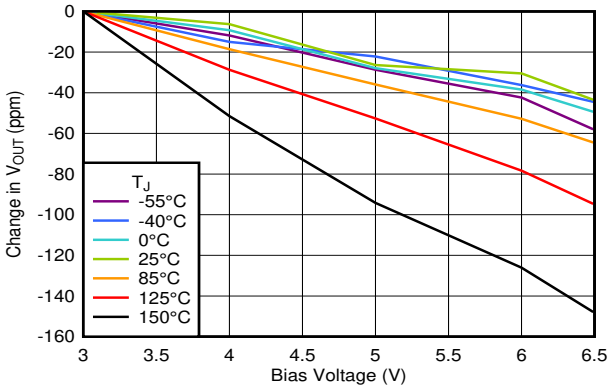
V_{IN} = 5.55 V, V_{OUT} = 5.15 V

図 7-53. Load Regulation (5-V Output)



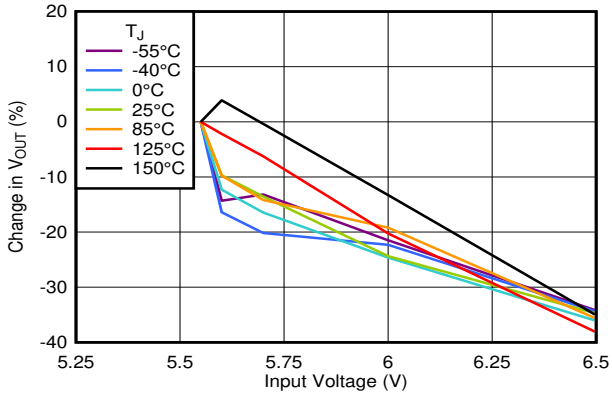
V_{OUT} = 0.5 V, I_{OUT} = 5 mA

図 7-54. Line Regulation vs V_{IN}



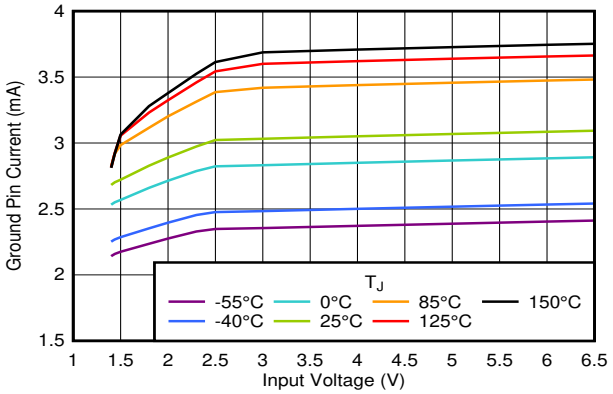
V_{OUT} = 0.5 V, V_{IN} = 1.1 V, I_{OUT} = 5 mA, V_{BIAS} = 5 V

図 7-55. Line Regulation With BIAS



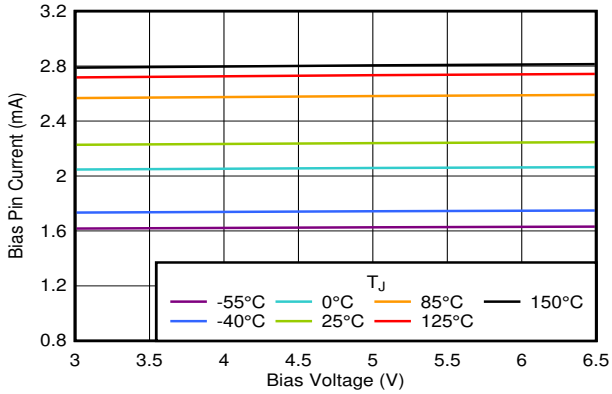
I_{OUT} = 5 mA

図 7-56. Line Regulation vs V_{IN} (5.2-V Output)



V_{BIAS} = 0 V, I_{OUT} = 5 mA

図 7-57. Ground Pin Current vs Input Voltage



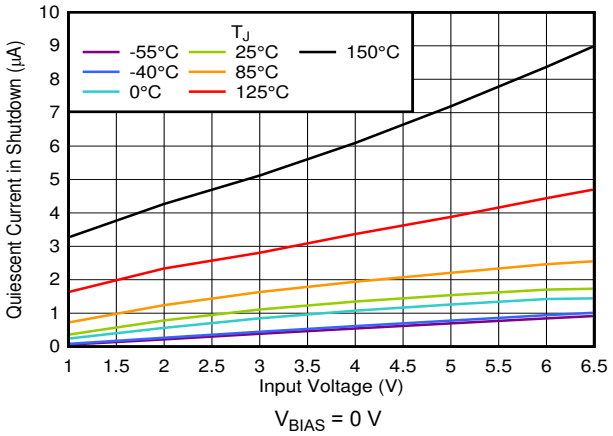
V_{IN} = 1.1 V, I_{OUT} = 5 mA

図 7-58. BIAS Pin Current vs Bias Voltage

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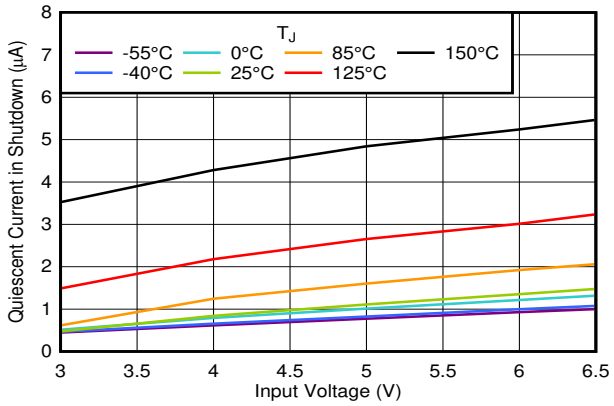
7.9 Typical Characteristics: TPS7A8301A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)



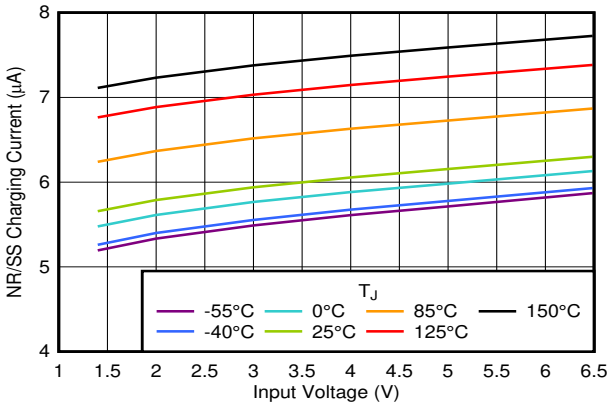
V_{BIAS} = 0 V

図 7-59. Shutdown Current vs Input Voltage



V_{IN} = 1.1 V

図 7-60. Shutdown Current vs Bias Voltage



V_{BIAS} = 0 V

図 7-61. $I_{NR/SS}$ Current vs Input Voltage

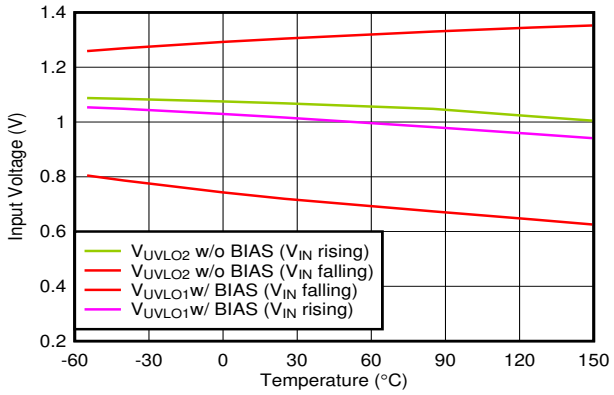
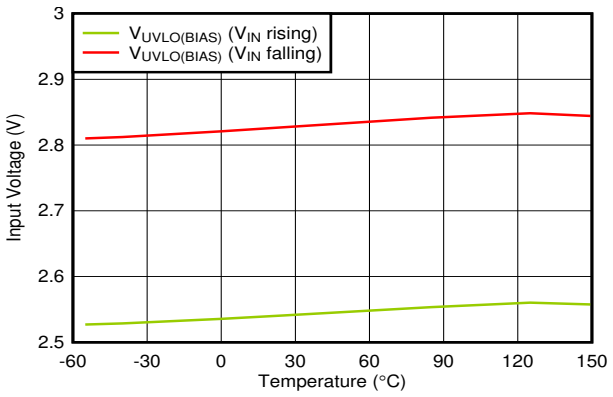
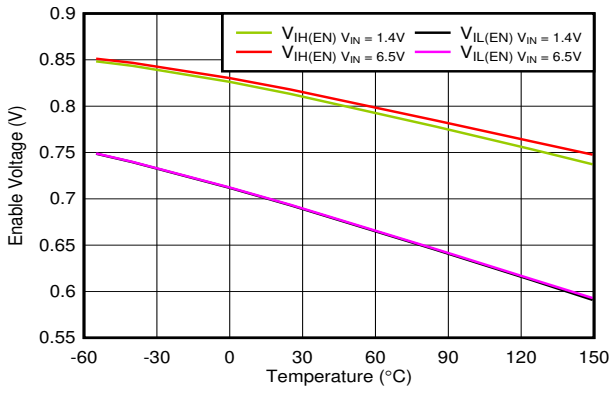


図 7-62. V_{IN} UVLO vs Temperature



V_{IN} = 1.1 V

図 7-63. V_{BIAS} UVLO vs Temperature



V_{IN} = 1.4 V, 6.5 V

図 7-64. Enable Threshold vs Temperature

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7.9 Typical Characteristics: TPS7A8301A (continued)

at T_A = 25°C, V_{IN} = 1.4 V or V_{IN} = $V_{OUT(nom)}$ + 0.3 V (whichever is greater), V_{BIAS} = open, $V_{OUT(nom)}$ = 0.8 V, V_{EN} = 1.1 V, C_{IN} = 10 µF, C_{OUT} = 22 µF, $C_{NR/SS}$ = 0 nF, C_{FF} = 0 nF, and PG pin pulled up to V_{IN} with 100 kΩ (unless otherwise noted)

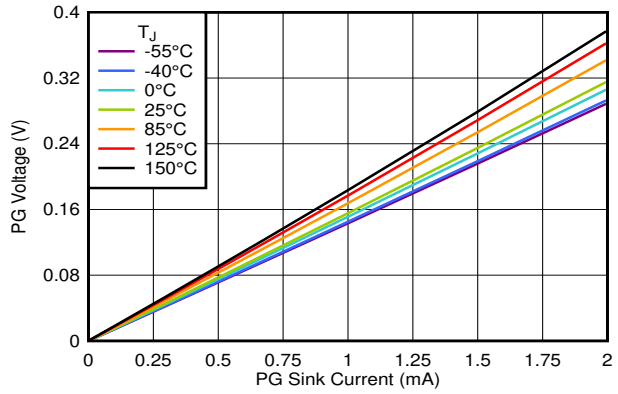


図 7-65. PG Voltage vs PG Current Sink

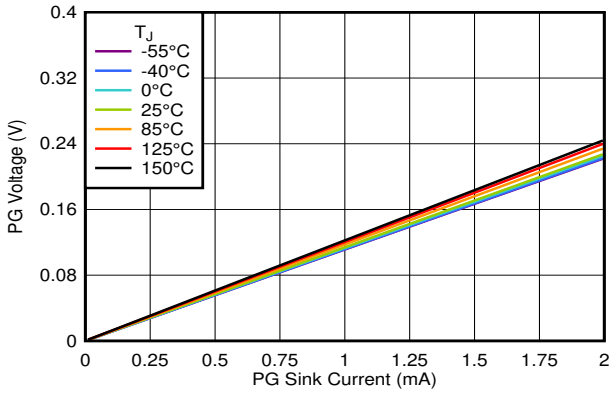


図 7-66. PG Voltage vs PG Current Sink

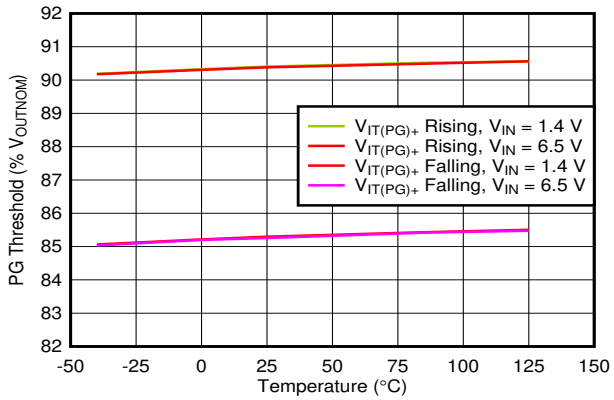


図 7-67. PG Threshold vs Temperature

8 Detailed Description

8.1 Overview

The TPS7A83A is a high-current (2 A), low-noise (4.4 μV_{RMS}), high-accuracy (0.75%), low-dropout linear voltage regulator (LDO). These features make the device a robust solution to solve many challenging problems in generating a clean, accurate power supply.

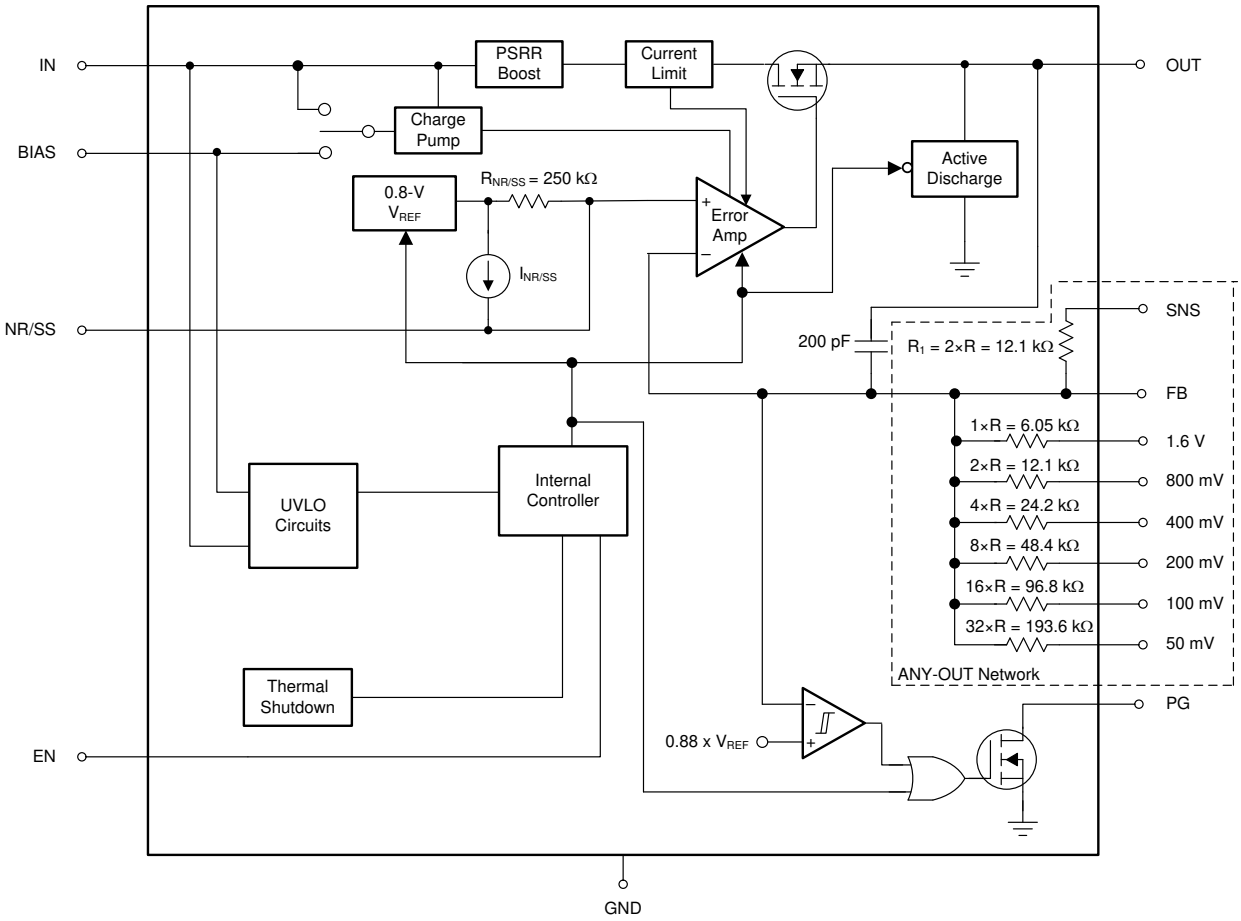
The TPS7A83A has several features that make the device useful in a variety of applications. 表 8-1 categorizes the functionalities shown in the *Functional Block Diagram* section.

表 8-1. Features

VOLTAGE REGULATION	SYSTEM START-UP	INTERNAL PROTECTION
High accuracy	Programmable soft-start	Foldback current limit
Low-noise, high-PSRR output	No sequencing requirement between BIAS, IN, and EN	Thermal shutdown
Fast transient response	Power-good output	
	Start-up with negative bias on OUT	

Overall, these features make the TPS7A83A the component of choice because of the versatility and ability of the device to generate a supply for most applications.

8.2 Functional Block Diagram



NOTE: For the ANY-OUT network, the ratios between the values are highly accurate as a result of matching, but the actual resistance can vary significantly from the numbers listed.

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8.3 Feature Description

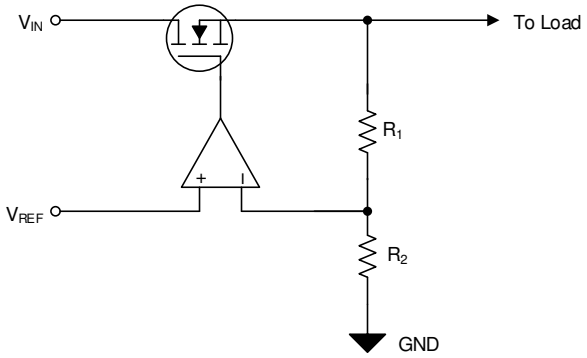
8.3.1 Voltage Regulation Features

8.3.1.1 DC Regulation

As 図 8-1 shows, an LDO functions as a class-B amplifier in which the input signal is the internal reference voltage (V_{REF}). V_{REF} is designed to have a very low bandwidth at the input to the error amplifier through the use of a low-pass filter ($V_{NR/SS}$).

As such, the reference can be considered as a pure dc input signal. The low output impedance of an LDO comes from the combination of the output capacitor and pass element. The pass element also presents a high input impedance to the source voltage when operating as a current source. A positive LDO can only source current because of the class-B architecture.

This device achieves a maximum of 0.75% output voltage accuracy primarily because of the high-precision band-gap voltage (V_{BG}) that creates V_{REF}. The low dropout voltage (V_{DO}) reduces the thermal power dissipation required by the device to regulate the output voltage at a given current level, thereby improving system efficiency. These features combine to make this device a good approximation of an ideal voltage source.



$V_{OUT} = V_{REF} \times (1 + R_1 / R_2)$.

図 8-1. Simplified Regulation Circuit

8.3.1.2 AC and Transient Response

The LDO responds quickly to a transient (large-signal response) on the input supply (line transient) or the output current (load transient) resulting from the LDO high-input impedance and low output-impedance across frequency. This same capability also means that the LDO has a high power-supply rejection ratio (PSRR) and, when coupled with a low internal noise-floor (e_n), the LDO approximates an ideal power supply in ac (small-signal) and large-signal conditions.

The choice of external component values optimizes the small- and large-signal response. The NR/SS capacitor ($C_{NR/SS}$) and feed-forward capacitor (C_{FF}) easily reduce the device noise floor and improve PSRR; see the *Optimizing Noise and PSRR* section for more information on optimizing the noise and PSRR performance.

8.3.2 System Start-Up Features

In many different applications, the power-supply output must turn on within a specific window of time to either ensure proper operation of the load or to minimize the loading on the input supply or other sequencing requirements. The LDO start up is well controlled and user adjustable, solving the demanding requirements faced by many power-supply design engineers in a simple fashion.

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8.3.2.1 Programmable Soft-Start (NR/SS)

Soft-start directly controls the output start-up time and indirectly controls the output current during start up (inrush current).

図 8-2 shows that the external capacitor at the NR/SS pin ($C_{NR/SS}$) sets the output start-up time by setting the rise time of the internal reference ($V_{NR/SS}$).

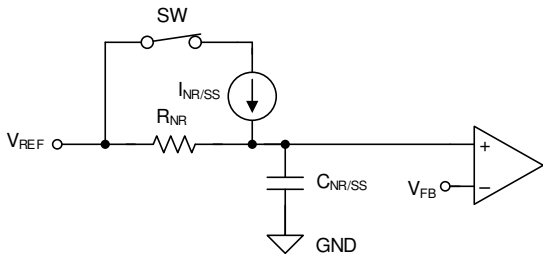


図 8-2. Simplified Soft-Start Circuit

8.3.2.2 Internal Sequencing

Controlling when a single power supply turns on can be difficult in a power distribution network (PDN) because of the high power levels inherent in a PDN, and the variations between the supplies. 図 8-3 and 表 8-2 show how the LDO turn-on and turn-off times are set by the enable circuit (EN) and undervoltage lockout circuits ($UVLO_{1,2(IN)}$ and $UVLO_{BIAS}$).

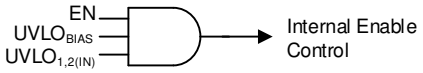


図 8-3. Simplified Turn-On Control

表 8-2. Internal Sequencing Functionality Table

INPUT VOLTAGE	BIAS VOLTAGE	ENABLE STATUS	LDO STATUS	ACTIVE DISCHARGE	POWER GOOD
$V_{IN} \geq V_{UVLO_1,2(IN)}$	$V_{BIAS} \geq V_{UVLO(BIAS)}$	EN = 1	On	Off	PG = 1 when $V_{OUT} \geq V_{IT(PG)}$
		EN = 0	Off	On	PG = 0
	$V_{BIAS} < V_{UVLO(BIAS)} + V_{HYS(BIAS)}$	EN = don't care	Off	On (1)	
$V_{IN} < V_{UVLO_1,2(IN)} - V_{HYS1,2(IN)}$	BIAS = don't care		Off		
IN = don't care	$V_{BIAS} \geq V_{UVLO(BIAS)}$		Off		

(1) The active discharge remains on as long as V_{IN} or V_{BIAS} provide enough headroom for the discharge circuit to function.

8.3.2.2.1 Enable (EN)

The enable signal (V_{EN}) is an active-high digital control that enables the LDO when the enable voltage is past the rising threshold ($V_{EN} \geq V_{IH(EN)}$) and disables the LDO when the enable voltage is below the falling threshold ($V_{EN} \leq V_{IL(EN)}$). The exact enable threshold is between $V_{IH(EN)}$ and $V_{IL(EN)}$ because EN is a digital control. Connect EN to V_{IN} or V_{BIAS} if enable functionality is not desired.

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8.3.2.2.2 Undervoltage Lockout (UVLO) Control

The UVLO circuits respond quickly to glitches on IN or BIAS and attempts to disable the output of the device if either of these rails collapse.

The local input capacitance prevents severe brownouts in most applications; see the *Undervoltage Lockout (UVLO)* section for more details.

8.3.2.2.3 Active Discharge

When either EN or UVLO is low, the device connects a resistor of several hundred ohms from V_{OUT} to GND, discharging the output capacitance.

Do not rely on the active discharge circuit for discharging large output capacitors when the input voltage drops below the targeted output voltage. Current flows from the output to the input (reverse current) when $V_{OUT} > V_{IN}$, which can cause damage to the device (when $V_{OUT} > V_{IN} + 0.3$ V); see the *Reverse Current* section for more details.

8.3.2.3 Power-Good Output (PG)

The PG signal provides an easy solution to meet demanding sequencing requirements because PG signals when the output nears the nominal value. PG can be used to signal other devices in a system when the output voltage is near, at, or above the set output voltage ($V_{OUT(nom)}$). 図 8-4 shows a simplified schematic.

The PG signal is an open-drain digital output that requires a pullup resistor to a voltage source and is active high. The PG circuit sets the PG pin into a high-impedance state to indicate that the power is good.

Using a large feed-forward capacitor (C_{FF}) delays the output voltage and, because the PG circuit monitors the FB pin, the PG signal can indicate a false positive. A simple solution to this scenario is to use an external voltage detector device, such as the TPS3890; see the *Feed-Forward Capacitor (C_{FF})* section for more information.

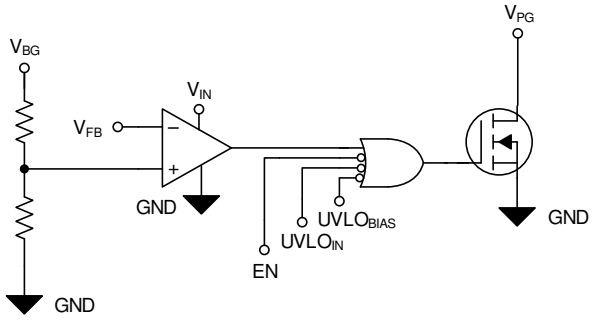


図 8-4. Simplified PG Circuit

8.3.3 Internal Protection Features

In many applications, fault events can occur that damage devices in the system. Short circuits and excessive heat are the most common fault events for power supplies. The TPS7A83A implements circuitry to protect the device and its load during these events. Continuously operating in these fault conditions or above a junction temperature of 125°C is not recommended because the long-term reliability of the device is reduced.

8.3.3.1 Foldback Current Limit (I_{CL})

The internal current limit circuit is used to protect the LDO against high load-current faults or shorting events. During a current-limit event, the LDO sources constant current; therefore, the output voltage falls with decreased load impedance. Thermal shutdown can activate during a current limit event because of the high power dissipation typically found in these conditions. To ensure proper operation of the current limit, minimize the inductances to the input and load. Continuous operation in current limit is not recommended.

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8.3.3.2 Thermal Protection (T_{sd})

The thermal shutdown circuit protects the LDO against excessive heat in the system, either resulting from current limit or high ambient temperature.

The output of the LDO turns off when the LDO temperature (junction temperature, T_J) exceeds the rising thermal shutdown temperature. The output turns on again after T_J decreases below the falling thermal shutdown temperature.

A high power dissipation across the device, combined with a high ambient temperature (T_A), can cause T_J to be greater than or equal to T_{sd}, triggering the thermal shutdown and causing the output to fall to 0 V. The LDO can cycle on and off when thermal shutdown is reached under these conditions.

Continuously triggering thermal shutdown can degrade long-term reliability.

8.4 Device Functional Modes

表 8-3 provides a quick comparison between the regulation and disabled operation.

表 8-3. Device Functional Modes Comparison

OPERATING MODE	PARAMETER				
	V_{IN}	V_{BIAS}	EN	I_{OUT}	T_J
Regulation(1)	$V_{IN} > V_{OUT(nom)} + V_{DO}$	$V_{BIAS} \geq V_{UVLO(BIAS)}$ (3)	$V_{EN} > V_{IH(EN)}$	$I_{OUT} < I_{CL}$	$T_J \leq T_{J(maximum)}$
Disabled(2)	$V_{IN} < V_{UVLO_1,2(IN)}$	$V_{BIAS} < V_{UVLO(BIAS)}$	$V_{EN} < V_{IL(EN)}$		$T_J > T_{sd}$
Current-limit operation	—	—	—	$I_{OUT} \geq I_{CL}$	—

(1) All table conditions must be met.
(2) The device is disabled when any condition is met.
(3) V_{BIAS} is only required for V_{IN} < 1.4 V.

8.4.1 Regulation

The device regulates the output to the nominal output voltage when all the conditions in 表 8-3 are met.

8.4.2 Disabled

When disabled, the pass device is turned off, the internal circuits are shut down, and the output voltage is actively discharged to ground by an internal resistor from the output to ground. See the *Active Discharge* section for additional information.

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9 Application and Implementation

Note

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9.1 Application Information

Successfully implementing an LDO in an application depends on the application requirements. This section discusses key device features and how to best implement them to achieve a reliable design.

9.1.1 External Component Selection

9.1.1.1 Adjustable Operation

The TPS7A83A can be used either with the internal ANY-OUT network or by using external resistors. Using the ANY-OUT network allows the TPS7A83A to be programmed from 0.8 V to 3.95 V. For an output voltage range greater than 3.95 V and up to 5.2 V, external resistors must be used. This configuration is referred to as the adjustable configuration of the TPS7A83A throughout this document. 図 9-1 shows that the output voltage is set by two resistors. 0.75% accuracy can be achieved with an external BIAS for V_{IN} lower than 2.2 V.

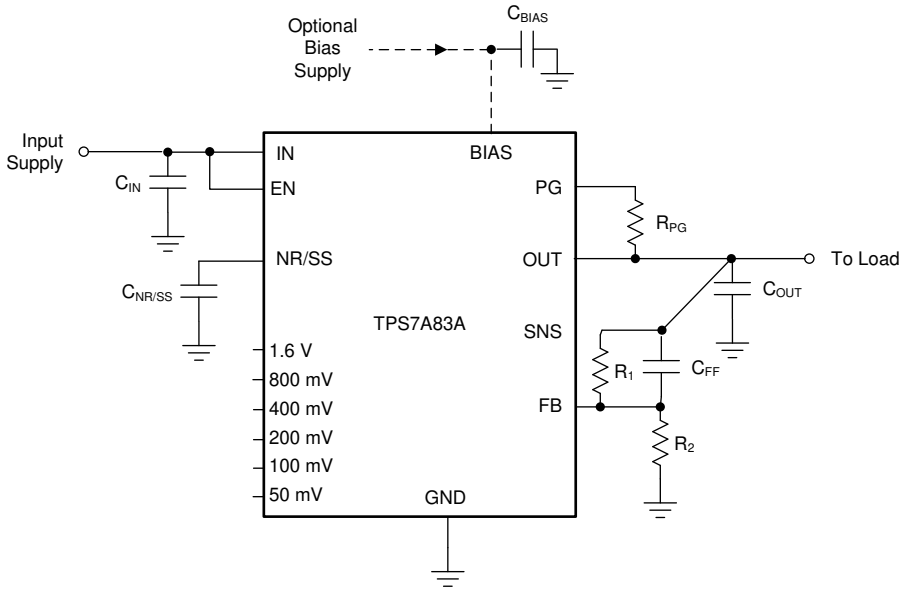


図 9-1. Adjustable Operation

Use 式 1 to calculate R_1 and R_2 for any output voltage range. This resistive network must provide a current equal to or greater than 5 µA for dc accuracy. Use an R_1 of approximately 12 kΩ to optimize the noise and PSRR.

$$V_{OUT} = V_{NR/SS} \times (1 + R_1 / R_2) \quad (1)$$

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表 9-1 shows the resistor combinations required to achieve several common rails using standard 1%-tolerance resistors.

表 9-1. Recommended Feedback-Resistor Values(1)

NOMINAL OUTPUT VOLTAGE (V)	FEEDBACK RESISTOR VALUES		CALCULATED OUTPUT VOLTAGE (V)
	R_1 (kΩ)	R_2 (kΩ)	
0.90	12.4	100	0.899
0.95	12.4	66.5	0.949
1.00	12.4	49.9	0.999
1.10	12.4	33.2	1.099
1.20	12.4	24.9	1.198
1.50	12.4	14.3	1.494
1.80	12.4	10	1.798
1.90	12.1	8.87	1.890
2.50	12.4	5.9	2.480
2.85	12.1	4.75	2.838
3.00	12.1	4.42	2.990
3.30	11.8	3.74	3.324
3.60	12.1	3.48	3.582
4.50	11.8	2.55	4.502
5.00	12.4	2.37	4.985

(1) R_1 is connected from OUT to FB; R_2 is connected from FB to GND.

9.1.1.2 ANY-OUT Programmable Output Voltage

The TPS7A83A can use either external resistors or the internally matched ANY-OUT feedback resistor network to set output voltage. The ANY-OUT resistors are accessible via pin 2 and pins 5 to 11 and are used to program the regulated output voltage. Each pin is can be connected to ground (active) or left open (floating), or connected to SNS. ANY-OUT programming is set by 式 2 as the sum of the internal reference voltage ($V_{NR/SS}$ = 0.8 V) plus the accumulated sum of the respective voltages assigned to each active pin; that is, 50mV (pin 5), 100mV (pin 6), 200mV (pin 7), 400mV (pin 9), 800mV (pin 10), or 1.6V (pin 11). 表 9-2 summarizes these voltage values associated with each active pin setting for reference. By leaving all program pins open or floating, the output is thereby programmed to the minimum possible output voltage equal to V_{FB}.

$$V_{OUT} = V_{NR/SS} + (\Sigma \text{ ANY-OUT Pins to Ground}) \quad (2)$$

表 9-2. ANY-OUT Programmable Output Voltage (RGR Package)

ANY-OUT PROGRAM PINS (Active Low)	ADDITIVE OUTPUT VOLTAGE LEVEL
Pin 5 (50mV)	50 mV
Pin 6 (100mV)	100 mV
Pin 7 (200mV)	200 mV
Pin 9 (400mV)	400 mV
Pin 10 (800mV)	800 mV
Pin 11 (1.6V)	1.6 V

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表 9-3 provides a full list of target output voltages and corresponding pin settings when the ANY-OUT pins are only tied to ground or left floating. The voltage setting pins have a binary weight; therefore, the output voltage can be programmed to any value from 0.8 V to 3.95 V in 50-mV steps when tying these pins to ground. There are several alternative ways to set the output voltage. The program pins can be driven using external general-purpose input/output pins (GPIOs), manually connected using 0-Ω resistors (or left open), or hardwired by the given layout of the printed circuit board (PCB) to set the ANY-OUT voltage. As with the adjustable operation, the output voltage is set according to 式 3 except that R_1 and R_2 are internally integrated and matched for higher accuracy. Tying any of the ANY-OUT pins to SNS can increase the resolution of the internal feedback network by lowering the value of R_1; see the *Increasing ANY-OUT Resolution for LILO Conditions* section for additional information.

$$V_{OUT} = V_{NR/SS} \times (1 + R_1 / R_2) \quad (3)$$

Note

For output voltages greater than 3.95 V, use a traditional adjustable configuration (see the *Adjustable Operation* section).

表 9-3. User-Configurable Output Voltage Settings

$V_{OUT(NOM)}$ (V)	50 mV	100 mV	200 mV	400 mV	800 mV	1.6 V	$V_{OUT(NOM)}$ (V)	50 mV	100 mV	200 mV	400 mV	800 mV	1.6 V
0.80	Open	Open	Open	Open	Open	Open	2.40	Open	Open	Open	Open	Open	GND
0.85	GND	Open	Open	Open	Open	Open	2.45	GND	Open	Open	Open	Open	GND
0.90	Open	GND	Open	Open	Open	Open	2.50	Open	GND	Open	Open	Open	GND
0.95	GND	GND	Open	Open	Open	Open	2.55	GND	GND	Open	Open	Open	GND
1.00	Open	Open	GND	Open	Open	Open	2.60	Open	Open	GND	Open	Open	GND
1.05	GND	Open	GND	Open	Open	Open	2.65	GND	Open	GND	Open	Open	GND
1.10	Open	GND	GND	Open	Open	Open	2.70	Open	GND	GND	Open	Open	GND
1.15	GND	GND	GND	Open	Open	Open	2.75	GND	GND	GND	Open	Open	GND
1.20	Open	Open	Open	GND	Open	Open	2.80	Open	Open	Open	GND	Open	GND
1.25	GND	Open	Open	GND	Open	Open	2.85	GND	Open	Open	GND	Open	GND
1.30	Open	GND	Open	GND	Open	Open	2.90	Open	GND	Open	GND	Open	GND
1.35	GND	GND	Open	GND	Open	Open	2.95	GND	GND	Open	GND	Open	GND
1.40	Open	Open	GND	GND	Open	Open	3.00	Open	Open	GND	GND	Open	GND
1.45	GND	Open	GND	GND	Open	Open	3.05	GND	Open	GND	GND	Open	GND
1.50	Open	GND	GND	GND	Open	Open	3.10	Open	GND	GND	GND	Open	GND
1.55	GND	GND	GND	GND	Open	Open	3.15	GND	GND	GND	GND	Open	GND
1.60	Open	Open	Open	Open	GND	Open	3.20	Open	Open	Open	Open	GND	GND
1.65	GND	Open	Open	Open	GND	Open	3.25	GND	Open	Open	Open	GND	GND
1.70	Open	GND	Open	Open	GND	Open	3.30	Open	GND	Open	Open	GND	GND
1.75	GND	GND	Open	Open	GND	Open	3.35	GND	GND	Open	Open	GND	GND
1.80	Open	Open	GND	Open	GND	Open	3.40	Open	Open	GND	Open	GND	GND
1.85	GND	Open	GND	Open	GND	Open	3.45	GND	Open	GND	Open	GND	GND
1.90	Open	GND	GND	Open	GND	Open	3.50	Open	GND	GND	Open	GND	GND
1.95	GND	GND	GND	Open	GND	Open	3.55	GND	GND	GND	Open	GND	GND
2.00	Open	Open	Open	GND	GND	Open	3.60	Open	Open	Open	GND	GND	GND
2.05	GND	Open	Open	GND	GND	Open	3.65	GND	Open	Open	GND	GND	GND
2.10	Open	GND	Open	GND	GND	Open	3.70	Open	GND	Open	GND	GND	GND
2.15	GND	GND	Open	GND	GND	Open	3.75	GND	GND	Open	GND	GND	GND
2.20	Open	Open	GND	GND	GND	Open	3.80	Open	Open	GND	GND	GND	GND
2.25	GND	Open	GND	GND	GND	Open	3.85	GND	Open	GND	GND	GND	GND
2.30	Open	GND	GND	GND	GND	Open	3.90	Open	GND	GND	GND	GND	GND
2.35	GND	GND	GND	GND	GND	Open	3.95	GND	GND	GND	GND	GND	GND

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9.1.1.3 ANY-OUT Operation

Considering the use of the ANY-OUT internal network (where the unit resistance of 1R is equal to 6.05 kΩ) the output voltage is set as shown in 図 9-2 by grounding the appropriate control pins. When grounded, all control pins add a specific voltage on top of the internal reference voltage ($V_{NR/SS}$ = 0.8 V). Use 式 4 and 式 5 to calculate the output voltage. 図 9-2 and 図 9-3 show a 0.9-V output voltage, respectively, that provides an example of the circuit usage with and without BIAS voltage.

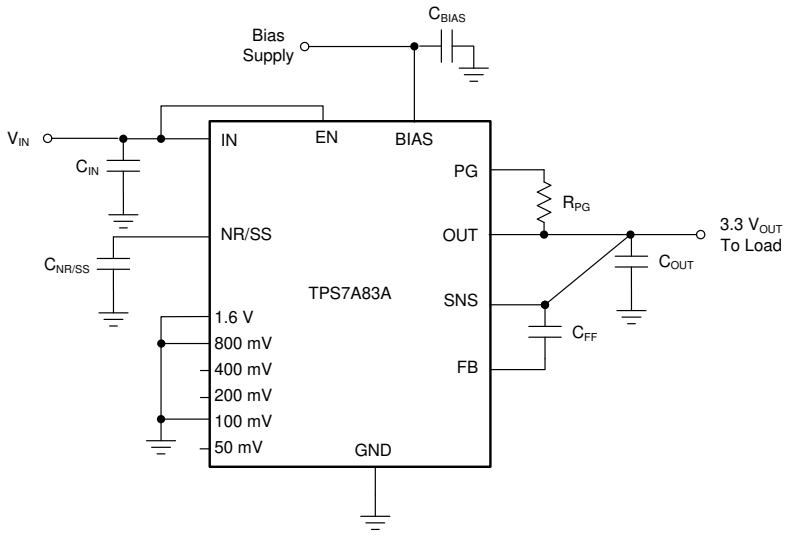


図 9-2. ANY-OUT Configuration Circuit (3.3-V Output, No External BIAS)

$$V_{OUT(nom)} = V_{NR/SS} + 1.6\ V + 0.8\ V + 0.1\ V = 0.8\ V + 1.6\ V + 0.8\ V + 0.1\ V = 3.3\ V \quad (4)$$

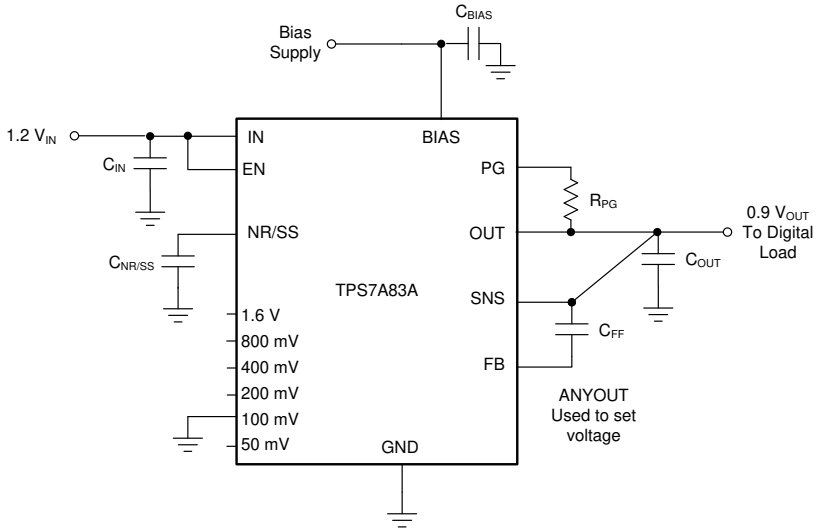


図 9-3. ANY-OUT Configuration Circuit (0.9-V Output With BIAS)

$$V_{OUT(nom)} = V_{NR/SS} + 0.1\ V = 0.8\ V + 0.1\ V = 0.9\ V \quad (5)$$

9.1.1.4 Increasing ANY-OUT Resolution for LILO Conditions

As with the adjustable operation, the output voltage is set according to 式 3, except that R_1 and R_2 are internally integrated and matched for higher accuracy. Tying any of the ANY-OUT pins to SNS can increase the resolution of the internal feedback network by lowering the value of R_1. One of the more useful pin combinations is to tie

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the 800mV pin to SNS, which reduces the resolution by 50% to 25 mV but limits the range. The new ANY-OUT ranges are 0.8 V to 1.175 V and 1.6 V to 1.975 V. 表 9-4 lists the new additive output voltage levels.

表 9-4. ANY-OUT Programmable Output Voltage With 800mV Tied to SNS (RGR Package)

ANY-OUT PROGRAM PINS (Active Low)	ADDITIVE OUTPUT VOLTAGE LEVEL
Pin 5 (50mV)	25 mV
Pin 6 (100mV)	50 mV
Pin 7 (200mV)	100 mV
Pin 9 (400mV)	200 mV
Pin 11 (1.6V)	800 mV

9.1.1.5 Recommended Capacitor Types

The TPS7A83A is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input, output, and noise-reduction pin (NR/SS). Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and COG-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, ceramic capacitance varies with operating voltage and temperature; derate ceramic capacitors by at least 50%. The input and output capacitors recommended herein account for a capacitance derating of approximately 50%, but at high V_{IN} and V_{OUT} conditions (for example, V_{IN} = 5.6 V to V_{OUT} = 5.2 V) the derating can be greater than 50% and must be taken into consideration.

9.1.1.6 Input and Output Capacitor Requirements (C_{IN} and C_{OUT})

The TPS7A83A is designed and characterized for operation with ceramic capacitors of 22 µF or greater (10 µF or greater of capacitance) at the output and 10 µF or greater (5 µF or greater of capacitance) at the input. Using at least a 22-µF capacitor is highly recommended at the input to minimize input impedance. Place the input and output capacitors as near as practical to the respective input and output pins to minimize trace parasitic. If the trace inductance from the input supply to the TPS7A83A is high, a fast current transient can cause V_{IN} to ring above the absolute maximum voltage rating and damage the device. This situation can be mitigated by additional input capacitors to dampen the ringing and to keep the ringing below the device absolute maximum ratings.

9.1.1.7 Feed-Forward Capacitor (C_{FF})

Although a feed-forward capacitor (C_{FF}) from the FB pin to the OUT pin is not required to achieve stability, a 10-nF external feed-forward capacitor optimizes the transient, noise, and PSRR performance. A higher capacitance C_{FF} can be used; however, the start-up time is longer, and the PG signal can incorrectly indicate that the output voltage is settled. For a detailed description, see the *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application report.

9.1.1.8 Noise-Reduction and Soft-Start Capacitor ($C_{NR/SS}$)

The TPS7A83A features a programmable, monotonic, voltage-controlled soft-start that is set with an external capacitor ($C_{NR/SS}$).The use of an external $C_{NR/SS}$ is highly recommended, especially to minimize in-rush current into the output capacitors. This soft-start eliminates power-up initialization problems when powering field-programmable gate arrays (FPGAs), digital signal processors (DSPs), or other processors. The controlled voltage ramp of the output also reduces peak in-rush current during start up, minimizing start-up transients to the input power bus.

To achieve a monotonic start-up, the TPS7A83A error amplifier tracks the voltage ramp of the external soft-start capacitor until the voltage approaches the internal reference. The soft-start ramp time depends on the soft-start charging current ($I_{NR/SS}$), the soft-start capacitance ($C_{NR/SS}$), and the internal reference ($V_{NR/SS}$). Use 式 6 to calculate the soft-start ramp time:

$$t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS} \quad (6)$$

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The noise-reduction capacitor, in conjunction with the noise-reduction resistor, forms a low-pass filter (LPF) that filters out the noise from the reference before being gained up with the error amplifier, thereby reducing the device noise floor. The LPF is a single-pole filter and 式 7 to calculates the cutoff frequency. The typical value of $R_{NR/SS}$ is 250 kΩ. Increasing the $C_{NR/SS}$ capacitor has a greater affect because the output voltage increases when the noise from the reference is gained up even more at higher output voltages. For low-noise applications, a 10-nF to 1-µF $C_{NR/SS}$ is recommended. When a $C_{NR/SS}$ capacitor gets larger, the capacitor leakage increases, causing a longer than expected start-up time.

$$f_{cutoff} = 1/ (2 \times \pi \times R_{NR/SS} \times C_{NR/SS}) \quad (7)$$

9.1.2 Start Up

9.1.2.1 Soft-Start (NR/SS)

The output of the device features a user-adjustable, monotonic, voltage-controlled soft-start that is set with an external capacitor ($C_{NR/SS}$). This soft-start eliminates power-up initialization problems when powering FPGAs, DSPs, or other processors. The controlled voltage ramp of the output also reduces peak inrush current during start-up, thus minimizing start-up transients to the input power bus.

The output voltage (V_{OUT}) rises proportionally to $V_{NR/SS}$during start-up as the LDO regulates so that the feedback voltage equals the NR/SS voltage ($V_{FB} = V_{NR/SS}$). As such, the time required for $V_{NR/SS}$ to reach its nominal value determines the rise time of V_{OUT} (start-up time).

Not using a noise-reduction capacitor on the NR/SS pin can result in output voltage overshoot of approximately 10%. Using a capacitor on the NR/SS pin minimizes the overshoot.

9.1.2.1.1 Inrush Current

Inrush current is defined as the current into the LDO at the IN pin during start-up. Inrush current then consists primarily of the sum of load current and the current used to charge the output capacitor. This current is difficult to measure because the input capacitor must be removed, which is not recommended. However, 式 8 can estimate this soft-start current:

$$I_{OUT}(t) = \left(\frac{C_{OUT} \times dV_{OUT}(t)}{dt} \right) + \left(\frac{V_{OUT}(t)}{R_{LOAD}} \right) \quad (8)$$

where:

- $V_{OUT}(t)$ is the instantaneous output voltage of the turn-on ramp
- $dV_{OUT}(t) / dt$ is the slope of the V_{OUT} ramp
- R_{LOAD} is the resistive load impedance

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9.1.2.2 Undervoltage Lockout (UVLO)

The UVLO circuits ensure that the device stays disabled before the input or bias supplies reach the minimum operational voltage range, and ensures that the device properly shuts down when either the input or BIAS supply collapses.

図 9-4 and 表 9-5 show one of the UVLO circuits being triggered to various input voltage events, assuming $V_{EN} \geq V_{IH(EN)}$.

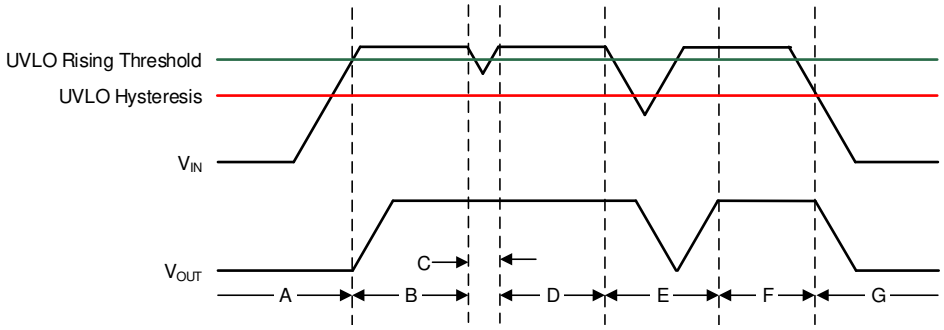


図 9-4. Typical UVLO Operation

表 9-5. Typical UVLO Operation Description

REGION	EVENT	V_{OUT} STATUS	COMMENT
A	Turn on, $V_{IN} \geq V_{UVLO_1,2(IN)}$, and $V_{BIAS} \geq V_{UVLO(BIAS)}$	Off	Start up
B	Regulation	On	Regulates to target V_{OUT}
C	Brownout, $V_{IN} \geq V_{UVLO_1,2(IN)} - V_{HYS_1,2(IN)}$ or $V_{BIAS} \geq V_{UVLO(BIAS)} - V_{HYS(BIAS)}$	On	The output can fall out of regulation but the device is still enabled
D	Regulation	On	Regulates to target V_{OUT}
E	Brownout, $V_{IN} < V_{UVLO_1,2(IN)} - V_{HYS_1,2(IN)}$ or $V_{BIAS} \geq V_{UVLO(BIAS)} - V_{HYS(BIAS)}$	Off	The device is disabled and the output falls because of the load and active discharge circuit. The device is re-enabled when the UVLO fault is removed when either the IN or BIAS UVLO rising threshold is reached by the input or bias voltage and a normal start up then follows.
F	Regulation	On	Regulates to target V_{OUT}
G	Turn off, $V_{IN} < V_{UVLO_1,2(IN)} - V_{HYS_1,2(IN)}$ or $V_{BIAS} < V_{UVLO(BIAS)} - V_{HYS(BIAS)}$	Off	The output falls because of the load and active discharge circuit

Similar to many other LDOs with this feature, the UVLO circuits take a few microseconds to fully assert. During this time, a downward line transient below approximately 0.8 V causes the UVLO to assert for a short time; however, the UVLO circuits do not have enough stored energy to fully discharge the internal circuits inside the device. When the UVLO circuits are not given enough time to fully discharge the internal nodes, the outputs are not fully disabled.

The effect of the downward line transient can be mitigated by using a larger input capacitor to increase the fall time of the input supply when operating near the minimum V_{IN}.

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9.1.2.3 Power-Good (PG) Function

The PG circuit monitors the voltage at the feedback pin to indicate the status of the output voltage. The PG circuit asserts whenever FB, V_{IN}, or EN are below their thresholds. 図 9-5 and 表 9-6 describe the PG operation versus the output voltage.

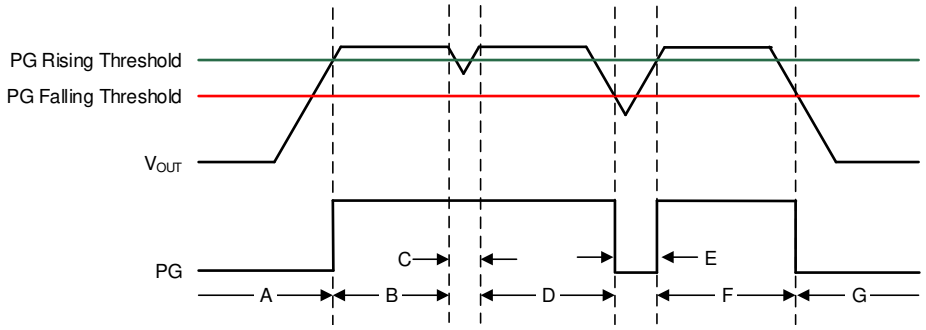


図 9-5. Typical PG Operation

表 9-6. Typical PG Operation Description

REGION	EVENT	PG STATUS	FB VOLTAGE
A	Turnon	0	$V_{FB} < V_{IT(PG)} + V_{HYS(PG)}$
B	Regulation	Hi-Z	$V_{FB} \geq V_{IT(PG)}$
C	Output voltage dip	Hi-Z	
D	Regulation	Hi-Z	
E	Output voltage dip	0	$V_{FB} < V_{IT(PG)}$
F	Regulation	Hi-Z	$V_{FB} \geq V_{IT(PG)}$
G	Turnoff	0	$V_{FB} < V_{IT(PG)}$

The PG pin is open-drain, and connecting a pullup resistor to an external supply enables others devices to receive power-good as a logic signal that can be used for sequencing. Make sure that the external pullup supply voltage results in a valid logic signal for the receiving device or devices.

To ensure proper operation of the PG circuit, the pullup resistor value must be from 10 kΩ and 100 kΩ. The lower limit of 10 kΩ results from the maximum pulldown strength of the PG transistor, and the upper limit of 100 kΩ results from the maximum leakage current at the PG node. If the pullup resistor is outside of this range, then the PG signal may not read a valid digital logic level.

Using a large C_{FF} with a small $C_{NR/SS}$ causes the PG signal to incorrectly indicate that the output voltage has settled during turnon. The C_{FF} time constant must be greater than the soft-start time constant to ensure proper operation of the PG during start-up. For a detailed description, see the *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application report.

The state of PG is only valid when the device operates above the minimum supply voltage. During short brownout events and at light loads, PG does not assert because the output voltage (therefore V_{FB}) is sustained by the output capacitance.

9.1.3 AC and Transient Performance

LDO ac performance includes power-supply rejection ratio, output-current transient response, and output noise. These metrics are primarily a function of open-loop gain, bandwidth, and phase margin that control the closed-loop input and output impedance of the LDO. The output noise is primarily a result of the reference and error amplifier noise.

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9.1.3.1 Power-Supply Rejection Ratio (PSRR)

PSRR is a measure of how well the LDO control loop rejects signals from V_{IN} to V_{OUT} across the frequency spectrum (usually 10 Hz to 10 MHz). 式 9 gives the PSRR calculation as a function of frequency for the input signal [$V_{IN}(f)$] and output signal [$V_{OUT}(f)$].

$$PSRR(dB) = 20Log_{10}\left(\frac{V_{IN}(f)}{V_{OUT}(f)}\right) \quad (9)$$

Even though PSRR is a loss in signal amplitude, PSRR is shown as positive values in decibels (dB) for convenience.

図 9-6 shows a simplified diagram of PSRR versus frequency.

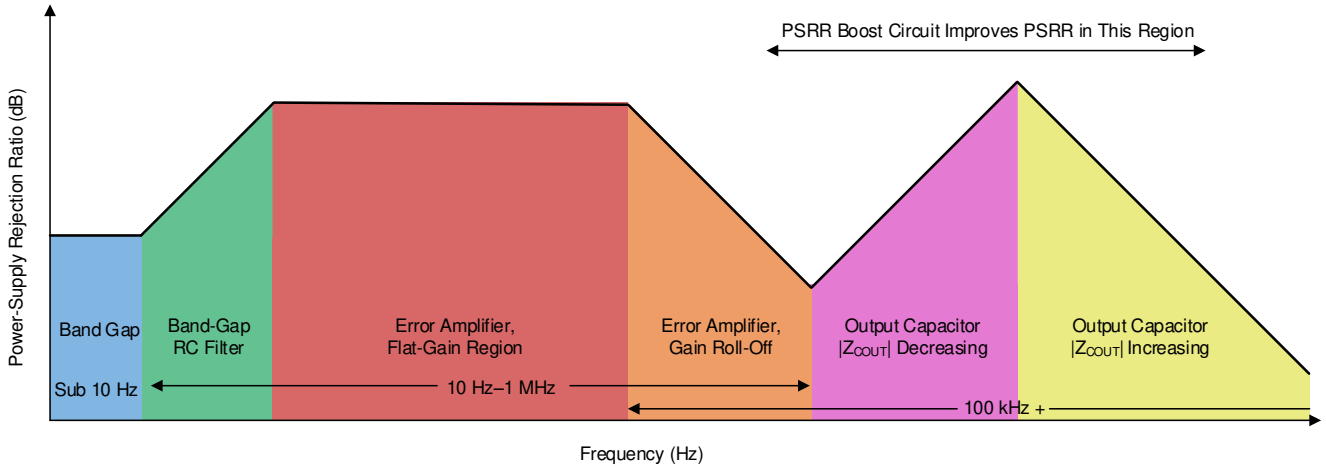


図 9-6. Power-Supply Rejection Ratio Diagram

An LDO is often employed not only as a dc/dc regulator, but also to provide exceptionally clean power-supply voltages that exhibit ultra-low noise and ripple to sensitive system components. This usage is especially true for the TPS7A83A.

The TPS7A83A features an innovative circuit to boost the PSRR from 200 kHz to 1 MHz; see 図 7-1. To achieve the maximum benefit of this PSRR boost circuit, use a capacitor with a minimum impedance in the 100-kHz to 1-MHz band.

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9.1.3.2 Output Voltage Noise

The TPS7A83A is designed for system applications where minimizing noise on the power-supply rail is critical to system performance. For example, the TPS7A83A can be used in a phase-locked loop (PLL)-based clocking circuit and can be used for minimum phase noise, or in test and measurement systems where even small power-supply noise fluctuations reduce system dynamic range.

LDO noise is defined as the internally-generated intrinsic noise created by the semiconductor circuits alone. This noise is the sum of various types of noise (such as shot noise associated with current-through-pin junctions, thermal noise caused by thermal agitation of charge carriers, flicker noise, or 1/f noise and dominates at lower frequencies as a function of 1/f). 図 9-7 shows a simplified output voltage noise density plot versus frequency.

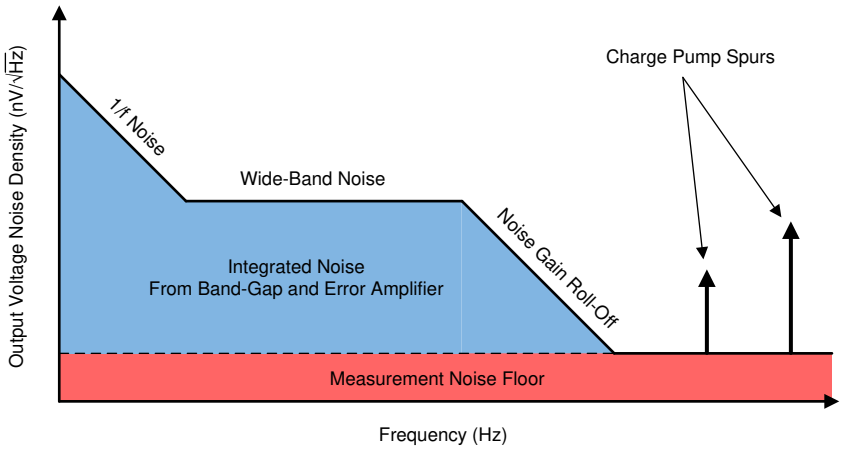


図 9-7. Output Voltage Noise Diagram

For further details, see the *How to Measure LDO Noise* white paper.

9.1.3.3 Optimizing Noise and PSRR

表 9-7 describes several ways how the ultra-low noise floor and PSRR of the device can be improved.

表 9-7. Effect of Various Parameters on AC Performance(1) (2)

PARAMETER	NOISE			PSRR		
	LOW-FREQUENCY	MID-FREQUENCY	HIGH-FREQUENCY	LOW-FREQUENCY	MID-FREQUENCY	HIGH-FREQUENCY
$C_{NR/SS}$	+++	No effect	No effect	+++	+	No effect
C_{FF}	++	+++	+	++	+++	+
C_{OUT}	No effect	+	+++	No effect	+	+++
$V_{IN} – V_{OUT}$	+	+	+	+++	+++	++
PCB layout	++	++	+	+	+++	+++

(1) The number of +'s indicates the improvement in noise or PSRR performance by increasing the parameter value.
(2) Shaded cells indicate the easiest improvement to noise or PSRR performance.

The noise-reduction capacitor, in conjunction with the noise-reduction resistor, forms a low-pass filter (LPF) that filters out the noise from the reference before being gained up with the error amplifier, thereby minimizing the output voltage noise floor. The LPF is a single-pole filter, and 式 10 calculates the cutoff frequency. The typical value of $R_{NR/SS}$ is 250 kΩ. The effect of the $C_{NR/SS}$ capacitor increases when $V_{OUT(nom)}$ increases because the noise from the reference is gained up when the output voltage increases. For low-noise applications, use a 10-nF to 1-µF $C_{NR/SS}$.

$$f_{cutoff} = 1 / (2 \times \pi \times R_{NR/SS} \times C_{NR/SS}) \quad (10)$$

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The feed-forward capacitor reduces output voltage noise by filtering out the mid-band frequency noise. The feed-forward capacitor can be optimized by placing a pole-zero pair near the edge of the loop bandwidth and pushing out the loop bandwidth, thus improving mid-band PSRR.

A larger C_{OUT} or multiple output capacitors reduces high-frequency output voltage noise and PSRR by reducing the high-frequency output impedance of the power supply.

Additionally, a higher input voltage improves the noise and PSRR because greater headroom is provided for the internal circuits. However, a high-power dissipation across the die increases the output noise because of the increase in junction temperature.

Good PCB layout improves the PSRR and noise performance by providing heat sinking at low frequencies and isolating V_{OUT} at high frequencies.

表 9-8 lists the output voltage noise for the 10-Hz to 100-kHz band at a 5-V output for a variety of conditions with an input voltage of 5.5 V and a load current of 2 A. The 5-V output was chosen as a worst-case nominal operation for output voltage noise.

表 9-8. Output Noise Voltage at a 5-V Output

OUTPUT VOLTAGE NOISE (μV_{RMS})	$C_{NR/SS}$ (nF)	C_{FF} (nF)	C_{OUT} (µF)
11.7	10	10	22
7.7	100	10	22
6	100	100	22
7.4	100	10	1000
5.8	100	100	1000

9.1.3.3.1 Charge Pump Noise

図 9-8 shows that the device internal charge pump generates a minimal amount of noise.

Using a BIAS rail minimizes the internal charge-pump noise when the internal voltage is clamped, thereby reducing the overall output noise floor.

The high-frequency components of the output voltage noise density curve are filtered out in most applications by using 10-nF to 100-nF bypass capacitors close to the load. Using a ferrite bead between the LDO output and the load input capacitors forms a pi-filter, further reducing the high-frequency noise contribution.

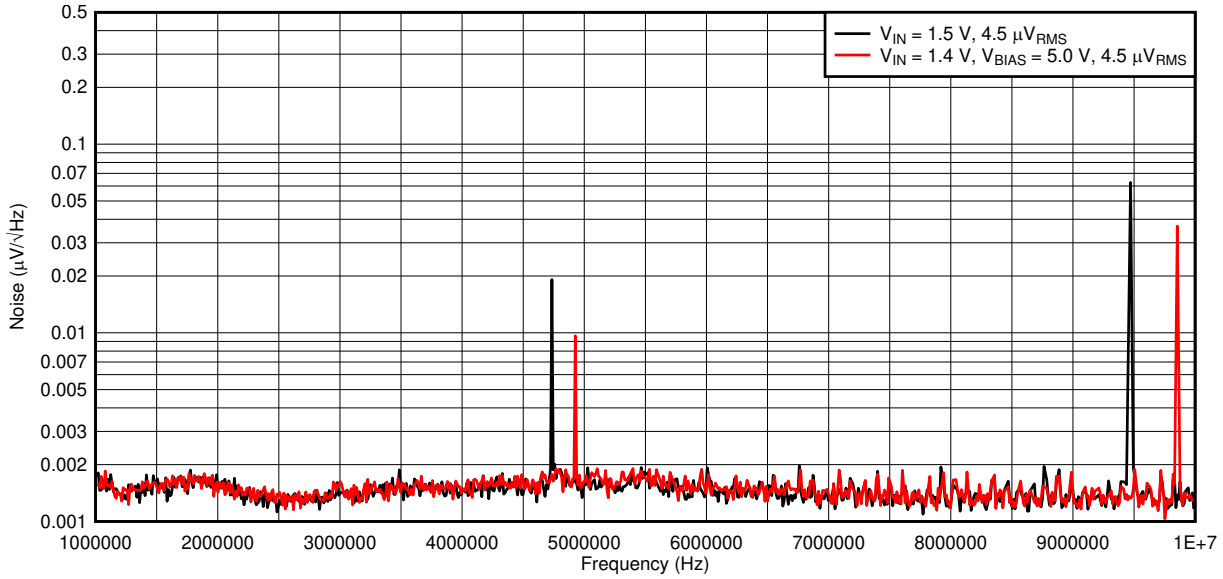


図 9-8. Charge Pump Noise

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9.1.3.4 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained. There are two key transitions during a load transient response: the transition from a light to a heavy load and the transition from a heavy to a light load. The regions shown in 図 9-9 and described in 表 9-9 are broken down in this section. Regions A, E, and H are where the output voltage is in steady-state.

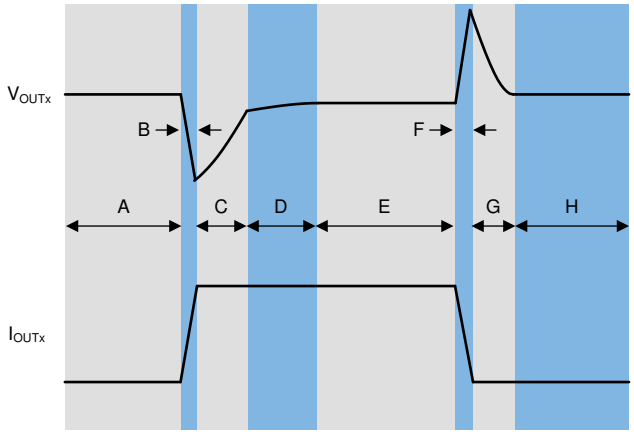


図 9-9. Load Transient Waveform

表 9-9. Load Transient Waveform Description

REGION	DESCRIPTION	COMMENT
A	Regulation	Regulation
B	Output current ramping	Initial voltage dip is a result of the depletion of the output capacitor charge
C	LDO responding to transient	Recovery from the dip results from the LDO increasing its sourcing current, and leads to output voltage regulation
D	Reaching thermal equilibrium	At high load currents the LDO takes some time to heat up. During this time the output voltage changes slightly.
E	Regulation	Regulation
F	Output current ramping	Initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase
G	LDO responding to transient	Recovery from the rise results from the LDO decreasing its sourcing current in combination with the load discharging the output capacitor
H	Regulation	Regulation

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The transient response peaks ($V_{OUT(max)}$ and $V_{OUT(min)}$) are improved by using more output capacitance; however, doing so slows down the recovery time (W_{rise} and W_{fall}). 図 9-10 shows these parameters during a load transient, with a given pulse duration (PW) and current levels ($I_{OUT(LO)}$ and $I_{OUT(HI)}$).

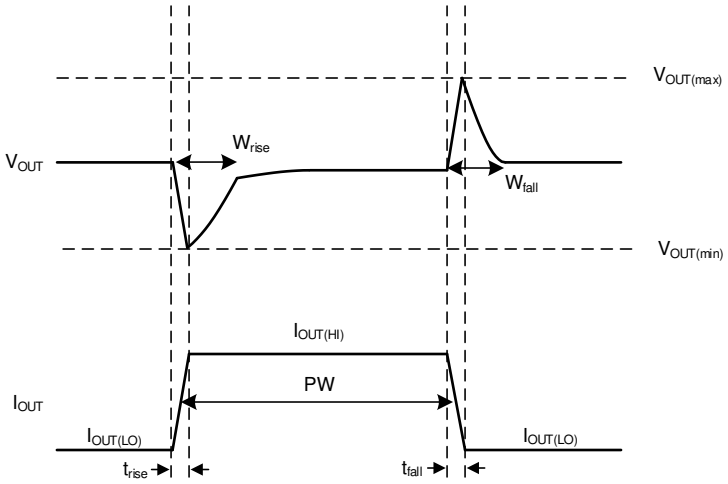


図 9-10. Simplified Load Transient Waveform

9.1.4 DC Performance

9.1.4.1 Output Voltage Accuracy (V_{OUT})

The device features an output voltage accuracy of 0.75% maximum, with BIAS, that includes the errors introduced by the internal reference, load regulation, line regulation, and operating temperature. Output voltage accuracy specifies minimum and maximum output voltage error, relative to the expected nominal output voltage stated as a percent.

9.1.4.2 Dropout Voltage (V_{DO})

Generally speaking, dropout voltage often refers to the minimum voltage difference between the input and output voltage ($V_{DO} = V_{IN} – V_{OUT}$) that is required for regulation. When V_{IN} drops below the required V_{DO} for the given load current, the device functions as a resistive switch and does not regulate output voltage. 図 9-11 shows that dropout voltage is proportional to the output current because the device is operating as a resistive switch.

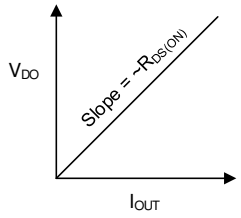


図 9-11. Dropout Voltage versus Output Current

Dropout voltage is affected by the drive strength for the gate of the pass element, which is nonlinear with respect to V_{IN} on this device because of the internal charge pump. Dropout voltage increases exponentially when the input voltage nears its maximum operating voltage.

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9.1.4.2.1 Behavior When Transitioning From Dropout Into Regulation

Some applications can have transients that place the LDO into dropout, such as slower ramps on V_{IN} for start-up or load transients. As with many other LDOs, the output can overshoot on recovery from these conditions.

図 9-12 shows that a ramping input supply can cause an LDO to overshoot on start-up when the slew rate and voltage levels are in the right range. This condition is easily avoided through either the use of an enable signal, or by increasing the soft-start time with $C_{SS/NR}$.

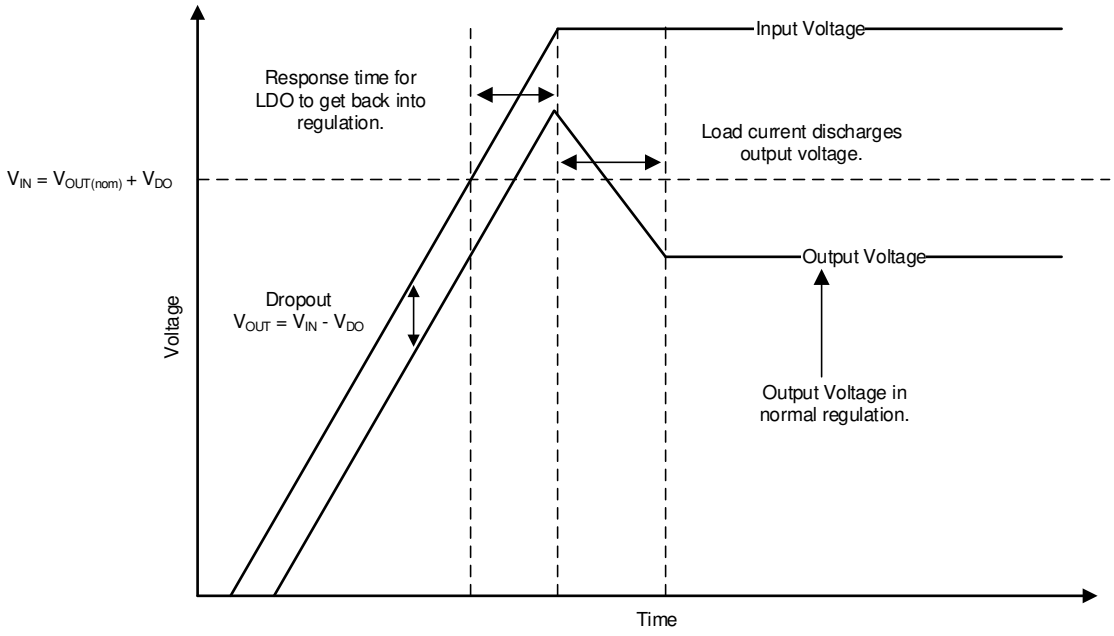


図 9-12. Start-Up Into Dropout

9.1.5 Sequencing Requirements

There is no sequencing requirement between the BIAS, IN, and EN pins in the TPS7A83A.

9.1.6 Negatively Biased Output

The TPS7A83A output can be negatively biased to the absolute maximum rating, without affecting the start-up condition.

9.1.7 Reverse Current

As with most LDOs, this device can be damaged by excessive reverse current.

Reverse current is current that flows through the body diode on the pass element instead of the normal conducting channel. This current flow, at high enough magnitudes, degrades long-term reliability of the device resulting from risks of electro-migration and excess heat being dissipated across the device. If the current flow gets high enough, a latch-up condition can be entered.

Conditions where excessive reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} > V_{IN} + 0.3$ V:

- If the device has a large C_{OUT} and the input supply collapses quickly with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

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If excessive reverse current flow is expected in the application, then external protection must be used to protect the device. 図 9-13 shows one approach of protecting the device.

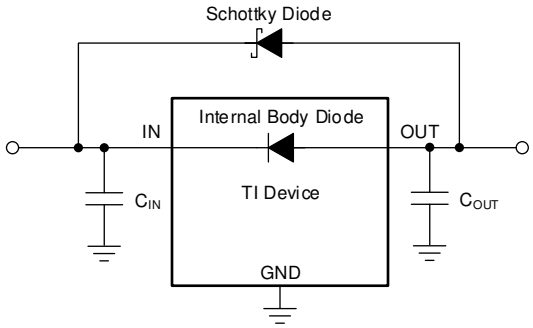


図 9-13. Example Circuit for Reverse Current Protection Using a Schottky Diode

9.1.8 Power Dissipation (P_D)

Circuit reliability demands that proper consideration is given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

As a first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. Use 式 11 to approximate P_D:

$$P_D = (V_{IN} – V_{OUT}) \times I_{OUT} \quad (11)$$

An important note is that power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the device allows for maximum efficiency across a wide range of output voltages.

The main heat conduction path for the device is through the thermal pad on the package. As such, the thermal pad must be soldered to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to any inner plane areas or to a bottom-side copper plane.

The maximum power dissipation determines the maximum allowable junction temperature (T_J) for the device. According to 式 12, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB, device package, and the temperature of the ambient air (T_A). 式 13 rewrites 式 12 for output current.

$$T_J = T_A + R_{\theta JA} \times P_D \quad (12)$$

$$I_{OUT} = (T_J – T_A) / [R_{\theta JA} \times (V_{IN} – V_{OUT})] \quad (13)$$

Unfortunately, this thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The $R_{\theta JA}$ recorded in the *Thermal Information* table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. For a well-designed thermal layout, $R_{\theta JA}$ is actually the sum of the VQFN package junction-to-case (bottom) thermal resistance ($R_{\theta JCbot}$) plus the thermal resistance contribution by the PCB copper.

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9.1.8.1 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics (Ψ_{JT} and Ψ_{JB}) are used in accordance with 式 14.

$$\Psi_{JT}: T_J = T_T + \Psi_{JT} \times P_D$$
$$\Psi_{JB}: T_J = T_B + \Psi_{JB} \times P_D \quad (14)$$

where:

- P_D is the power dissipated as explained in 式 11
- T_T is the temperature at the center-top of the device package, and
- T_B is the PCB surface temperature measured 1 mm from the device package and centered on the package edge

9.1.8.2 Recommended Area for Continuous Operation (RACO)

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. As shown in 図 9-14, the recommended area for continuous operation for a linear regulator can be separated into the following parts:

- Limited by dropout: Dropout voltage limits the minimum differential voltage between the input and the output ($V_{IN} – V_{OUT}$) at a given output current level; see the *Dropout Voltage (V_{DO})* section for more details.
- Limited by rated output current: The rated output current limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- Limited by thermals: The shape of the slope is given by 式 13. The slope is nonlinear because the junction temperature of the LDO is controlled by the power dissipation across the LDO; therefore, when $V_{IN} – V_{OUT}$ increases, the output current must decrease in order to ensure that the rated junction temperature of the device is not exceeded. Exceeding this rating can cause the device to fall out of specifications and reduces long-term reliability.
- Limited by V_{IN} range: The rated input voltage range governs both the minimum and maximum of $V_{IN} – V_{OUT}$.

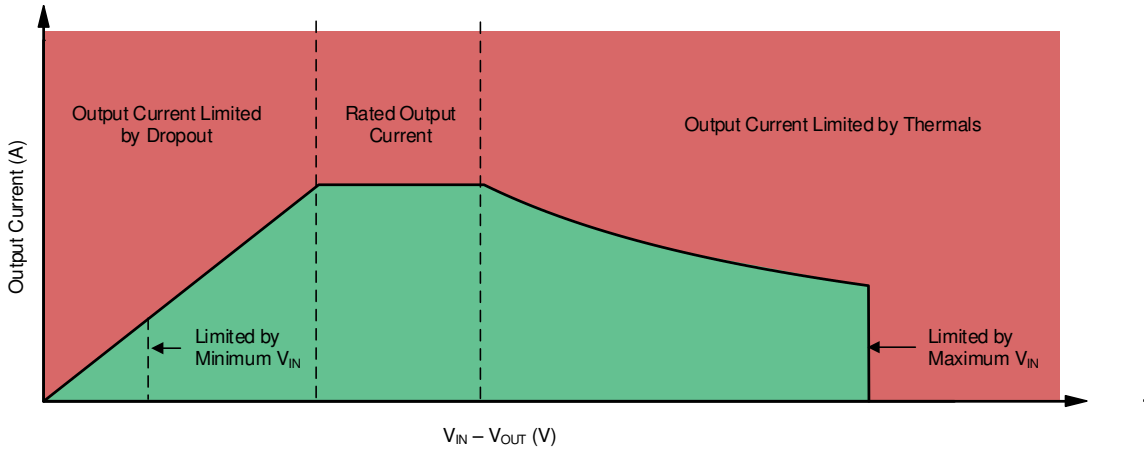


図 9-14. Continuous Operation Slope Region Description

図 9-15 to 図 9-20 show the recommended area of operation curves for this device on a JEDEC-standard, high-K board with a $R_{\theta JA}$ = 43.4°C/W.

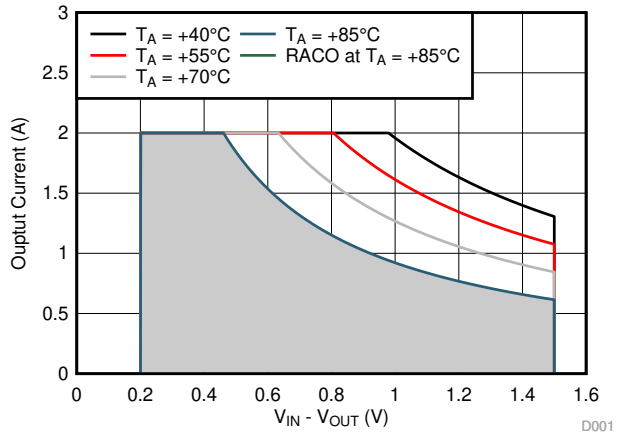


図 9-15. Recommended Area for Continuous Operation for V_{OUT} = 0.9 V

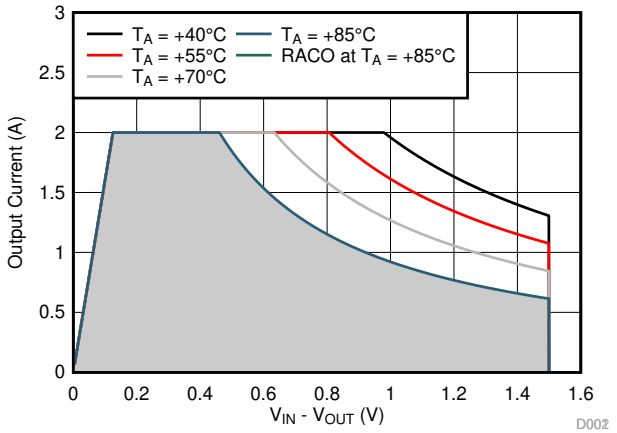


図 9-16. Recommended Area for Continuous Operation for V_{OUT} = 1.2 V

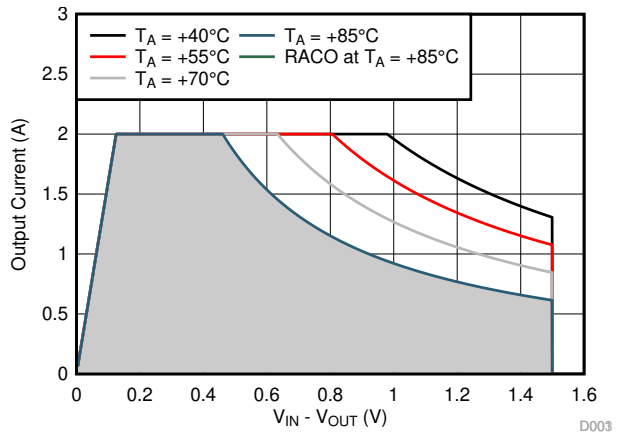


図 9-17. Recommended Area for Continuous Operation for V_{OUT} = 1.8 V

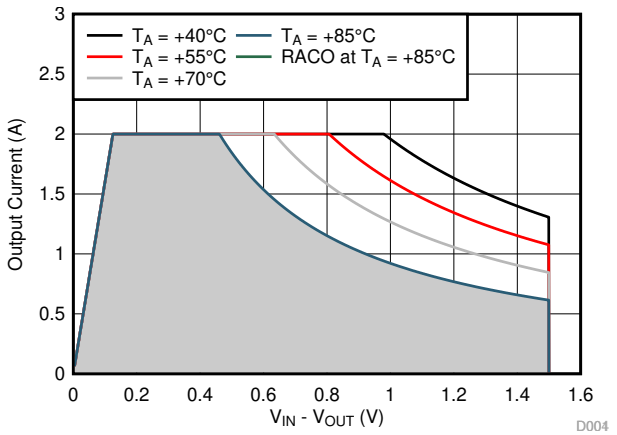


図 9-18. Recommended Area for Continuous Operation for V_{OUT} = 2.5 V

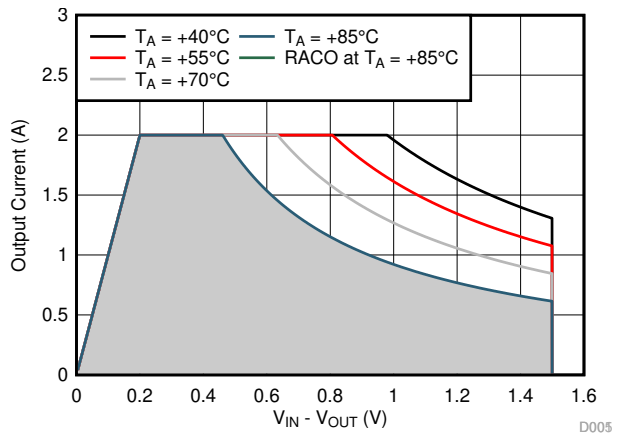


図 9-19. Recommended Area for Continuous Operation for V_{OUT} = 3.3 V

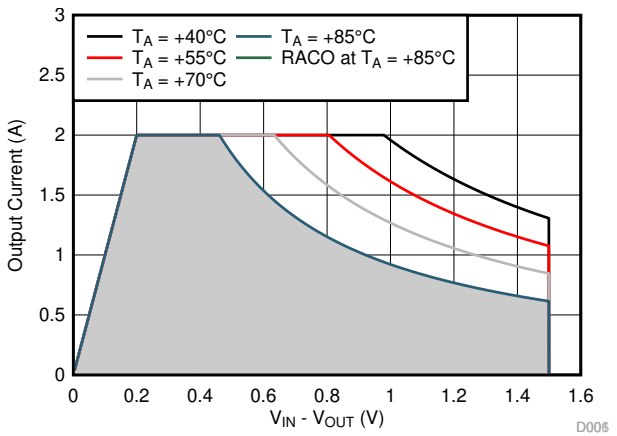


図 9-20. Recommended Area for Continuous Operation for V_{OUT} = 5 V

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9.2 Typical Application

The TPS7A83A uses the ANY-OUT configuration to regulate a 2-A load requiring good PSRR at high frequency with low-noise at 0.9 V using a 1.2-V input voltage and a 5-V bias supply. 図 9-21 provides a schematic for this typical application circuit.

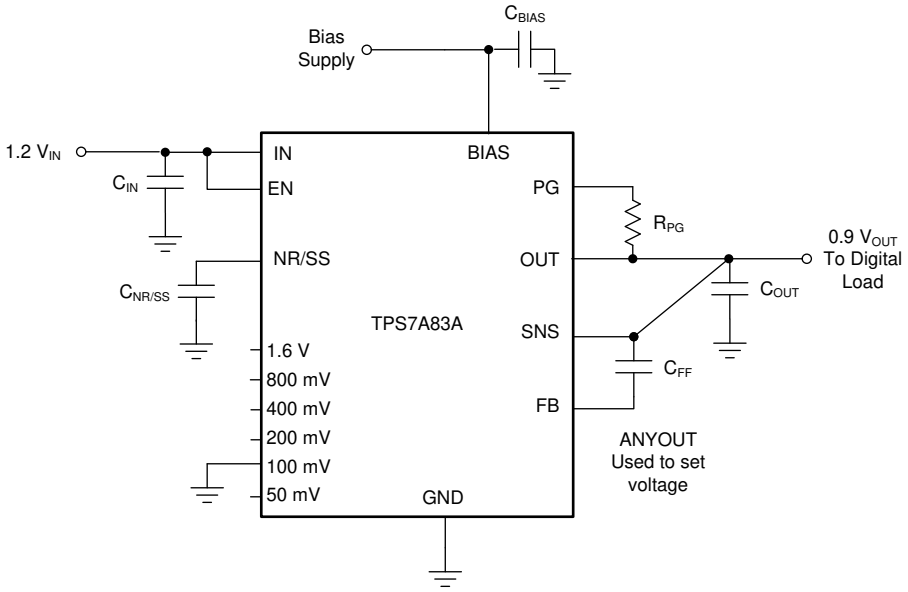


図 9-21. TPS7A83A Typical Application: Low-Input, Low-Output (LILO) Voltage Conditions

9.2.1 Design Requirements

For this design example, use the parameters listed in 表 9-10 as the input parameters.

表 9-10. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Input voltage	1.2 V, ±3%, provided by the dc/dc converter switching at 500 kHz
Bias voltage	5 V, ±5%
Output voltage	0.9 V, ±1%
Output current	2 A (maximum), 100 mA (minimum)
RMS noise, 10 Hz to 100 kHz	< 10 μV_{RMS}
PSRR at 500 kHz	> 40 dB
Start-up time	< 25 ms

9.2.2 Detailed Design Procedure

At 2 A, the dropout of the TPS7A83A has 180-mV maximum dropout over temperature, thus a 400-mV headroom is sufficient for operation over both input and output voltage accuracy. The bias rail is provided for better performance for the LILO conditions. As per 表 9-10, the PSRR is greater than 40 dB in these conditions and noise is less than 10 μV_{RMS}.

The ANY-OUT internal resistor network is also used for maximum accuracy.

To achieve 0.9 V on the output, the 100mV pin is grounded. 式 15 describes how the voltage value of 100 mV is added to the 0.8-V internal reference voltage for $V_{OUT(nom)}$ equal to 0.9 V.

$$V_{OUT(nom)} = V_{NR/SS} + 0.1\ V = 0.8\ V + 0.1\ V = 0.9\ V \quad (15)$$

Input and output capacitors are selected in accordance with the *External Component Selection* section. Ceramic capacitors of 10 µF for the input and one 22-µF capacitor for the output are selected.

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To satisfy the required start-up time and still maintain low-noise performance, a 100-nF $C_{NR/SS}$ is selected. 式 16 calculates this value.

$$t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS} \quad (16)$$

At the 2-A maximum load, the internal power dissipation is 0.6 W and corresponds to a 26.04°C junction temperature rise for the RGR package on a standard JEDEC board. With an 55°C maximum ambient temperature, the junction temperature is at 94.06°C. To further minimize noise, a feed-forward capacitor (C_{FF}) of 10 nF is selected.

9.2.3 Application Curves

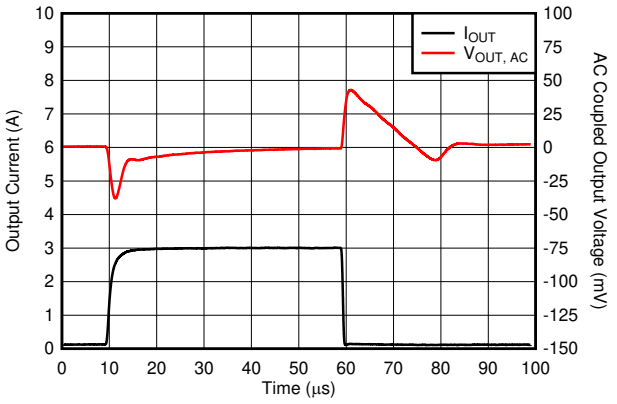


図 9-22. Output Load Transient Response

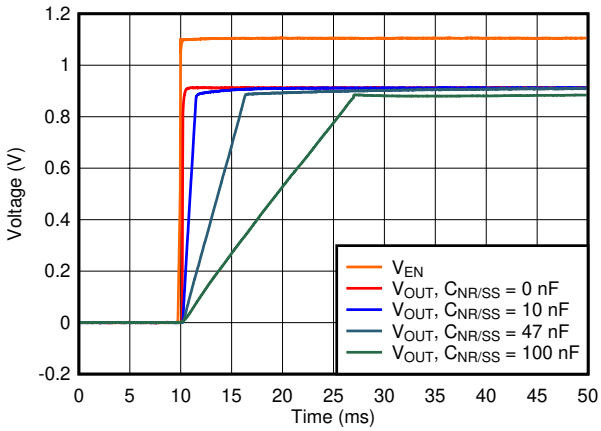


図 9-23. Output Start-Up Response

10 Power Supply Recommendations

The TPS7A83A is designed to operate from an input voltage supply range from 1.1 V to 6.5 V. If the input supply is less than 1.4 V, then a bias rail of at least 3 V must be used. The input voltage range provides adequate headroom in order for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR may help improve output noise performance.

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11 Layout

11.1 Layout Guidelines

For best overall performance, place all circuit components on the same side of the circuit board and as near as practical to the respective LDO pin connections. Place ground return connections to the input and output capacitor, and to the LDO ground pin as close as possible to each other, connected by a wide, component-side, copper surface. The use of vias and long traces to the input and output capacitors is strongly discouraged and negatively affects system performance. The grounding and layout scheme shown in 図 11-1 minimizes inductive parasitics, and thereby reduces load-current transients, minimizes noise, and increases circuit stability.

Using a ground reference plane either embedded in the PCB itself or located on the bottom side of the PCB opposite the components is beneficial to the layout. This reference plane serves to assure accuracy of the output voltage, shield noise, and behaves similarly to a thermal plane to spread (or sink) heat from the LDO device when connected to the thermal pad. In most applications, this ground plane is necessary to meet thermal requirements.

11.2 Layout Example

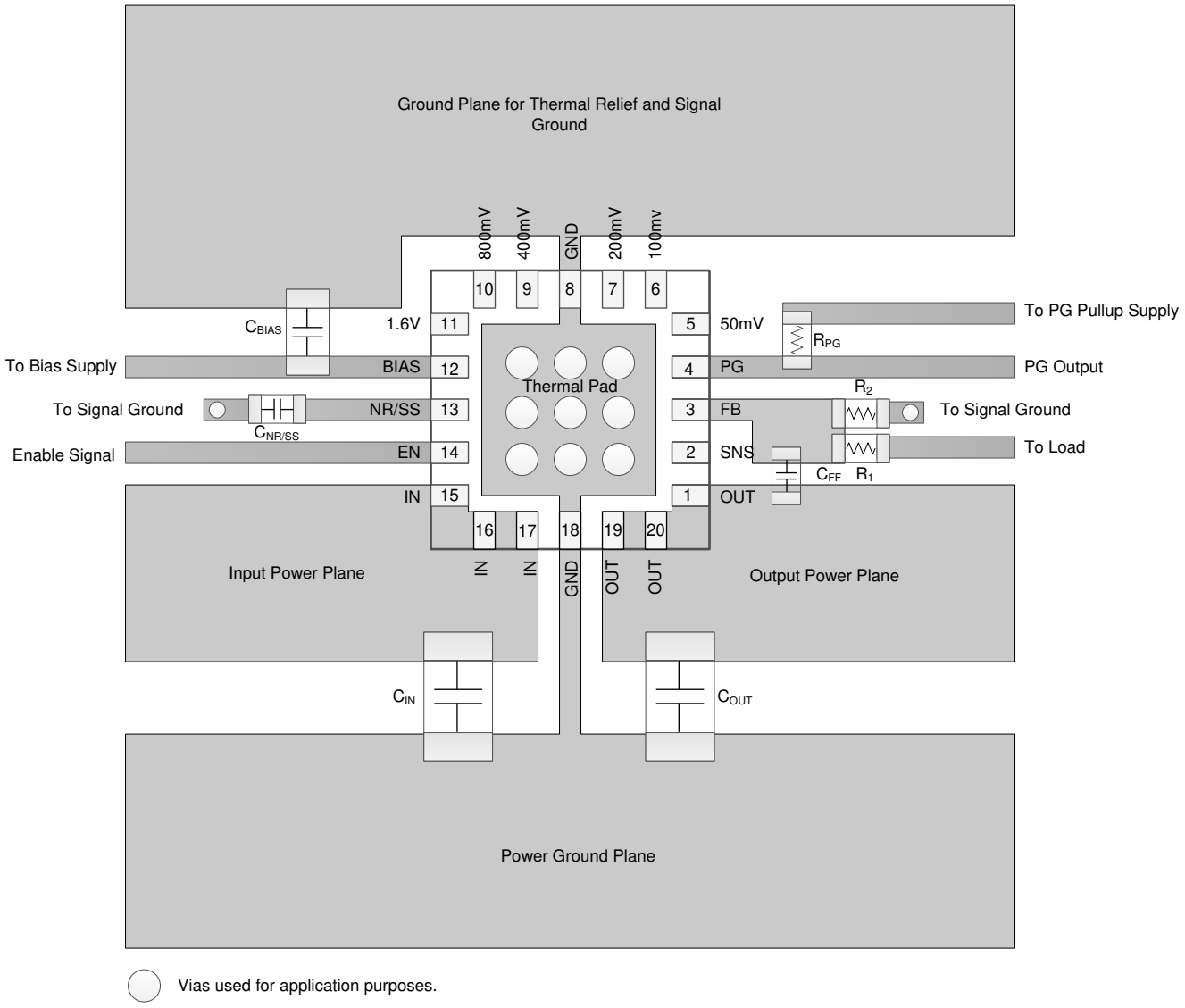


図 11-1. Example Layout

12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 Evaluation Models

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS7A8300. 表 12-1 shows the summary information for this fixture.

表 12-1. Design Kits and Evaluation Models

NAME	EVALUATION MODEL
TPS7A8300EVM-579 Evaluation Module	SBVU021

The EVM can be requested at the Texas Instruments web site through the TPS7A8300 product folder.

12.1.1.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS7A83A device is available through the TPS7A83A product folder under simulation models.

12.1.2 Device Nomenclature

表 12-2. Ordering Information(1)

PRODUCT	DESCRIPTION
TPS7A8300A **YYYZ**	**YYY** is the package designator **Z** is the package quantity

(1) For the most current package and ordering information see the Package Option Addendum at the end of the this document, or see the device product folder at www.ti.com.

12.2 Documentation Support

12.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *High-Accuracy, Overvoltage and Undervoltage Monitor* data sheet
- Texas Instruments, *TPS7A8300EVM-579 Evaluation Module* user's guide
- Texas Instruments, *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application report
- Texas Instruments, *TPS3890 Low Quiescent Current, 1% Accurate Supervisor with Programmable Delay* data sheet

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 サポート・リソース

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12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A8300ARGRR	Active	Production	VQFN (RGR) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8300A
TPS7A8300ARGRR.A	Active	Production	VQFN (RGR) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8300A
TPS7A8300ARGRRG4	Active	Production	VQFN (RGR) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8300A
TPS7A8300ARGRRG4.A	Active	Production	VQFN (RGR) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8300A
TPS7A8300ARGRT	Active	Production	VQFN (RGR) | 20	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8300A
TPS7A8300ARGRT.A	Active	Production	VQFN (RGR) | 20	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8300A
TPS7A8300ARGWR	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1F5H
TPS7A8300ARGWR.A	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1F5H
TPS7A8300ARGWRG4	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1F5H
TPS7A8300ARGWRG4.A	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1F5H
TPS7A8300ARGWT	Active	Production	VQFN (RGW) | 20	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1F5H
TPS7A8300ARGWT.A	Active	Production	VQFN (RGW) | 20	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1F5H
TPS7A8301ARGRR	Active	Production	VQFN (RGR) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8301R
TPS7A8301ARGRR.A	Active	Production	VQFN (RGR) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8301R
TPS7A8301ARGWR	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8301W
TPS7A8301ARGWR.A	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8301W

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

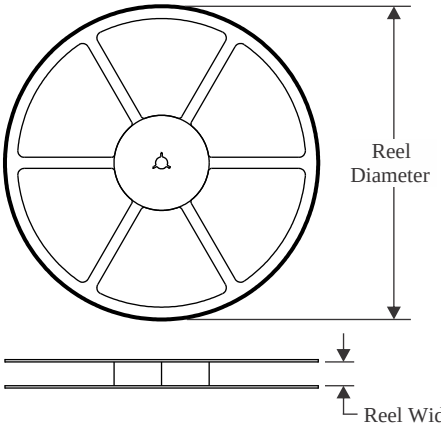
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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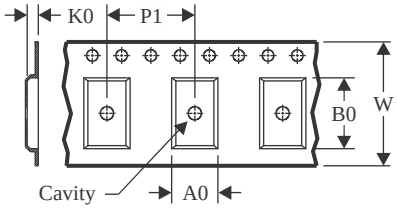
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

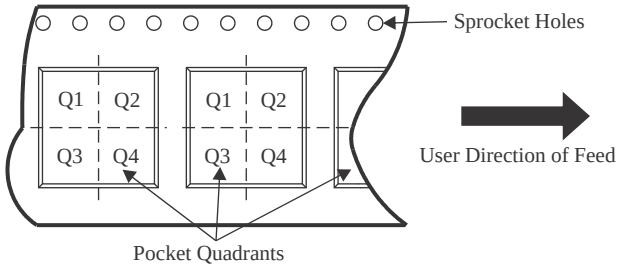


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

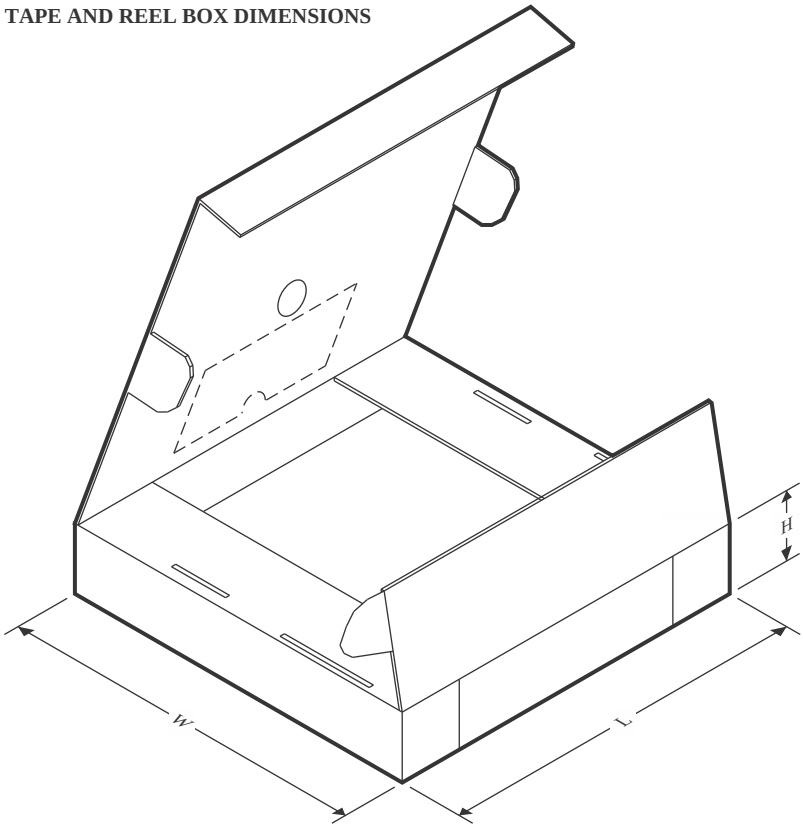
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A8300ARGRR	VQFN	RGR	20	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q2
TPS7A8300ARGRRG4	VQFN	RGR	20	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q2
TPS7A8300ARGRT	VQFN	RGR	20	250	180.0	12.4	3.75	3.75	1.15	8.0	12.0	Q2
TPS7A8300ARGWR	VQFN	RGW	20	3000	330.0	12.4	5.3	5.3	1.3	8.0	12.0	Q2
TPS7A8300ARGWRG4	VQFN	RGW	20	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
TPS7A8300ARGWT	VQFN	RGW	20	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
TPS7A8301ARGRR	VQFN	RGR	20	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q2
TPS7A8301ARGWR	VQFN	RGW	20	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A8300ARGRR	VQFN	RGR	20	3000	360.0	360.0	36.0
TPS7A8300ARGRRG4	VQFN	RGR	20	3000	367.0	367.0	35.0
TPS7A8300ARGRT	VQFN	RGR	20	250	210.0	185.0	35.0
TPS7A8300ARGWR	VQFN	RGW	20	3000	356.0	356.0	36.0
TPS7A8300ARGWRG4	VQFN	RGW	20	3000	367.0	367.0	35.0
TPS7A8300ARGWT	VQFN	RGW	20	250	210.0	185.0	35.0
TPS7A8301ARGRR	VQFN	RGR	20	3000	360.0	360.0	36.0
TPS7A8301ARGWR	VQFN	RGW	20	3000	360.0	360.0	36.0

GENERIC PACKAGE VIEW

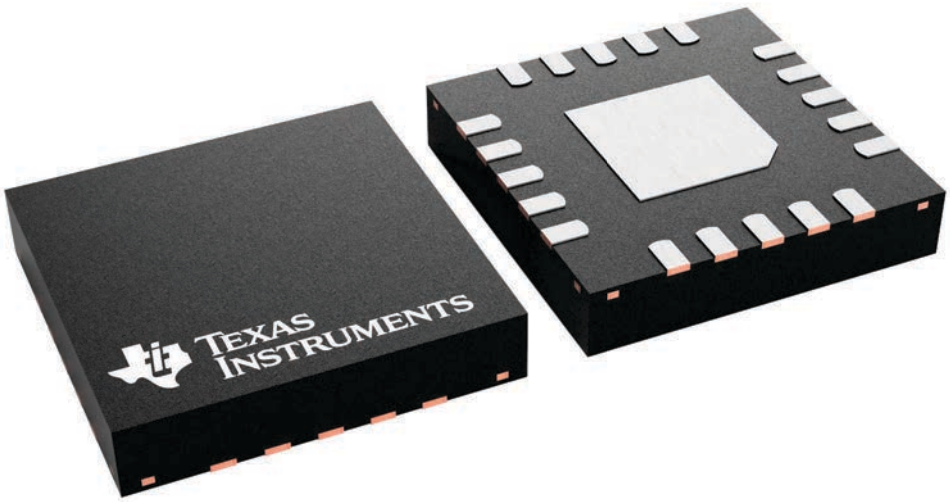
RGW 20

VQFN - 1 mm max height

5 x 5, 0.65 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



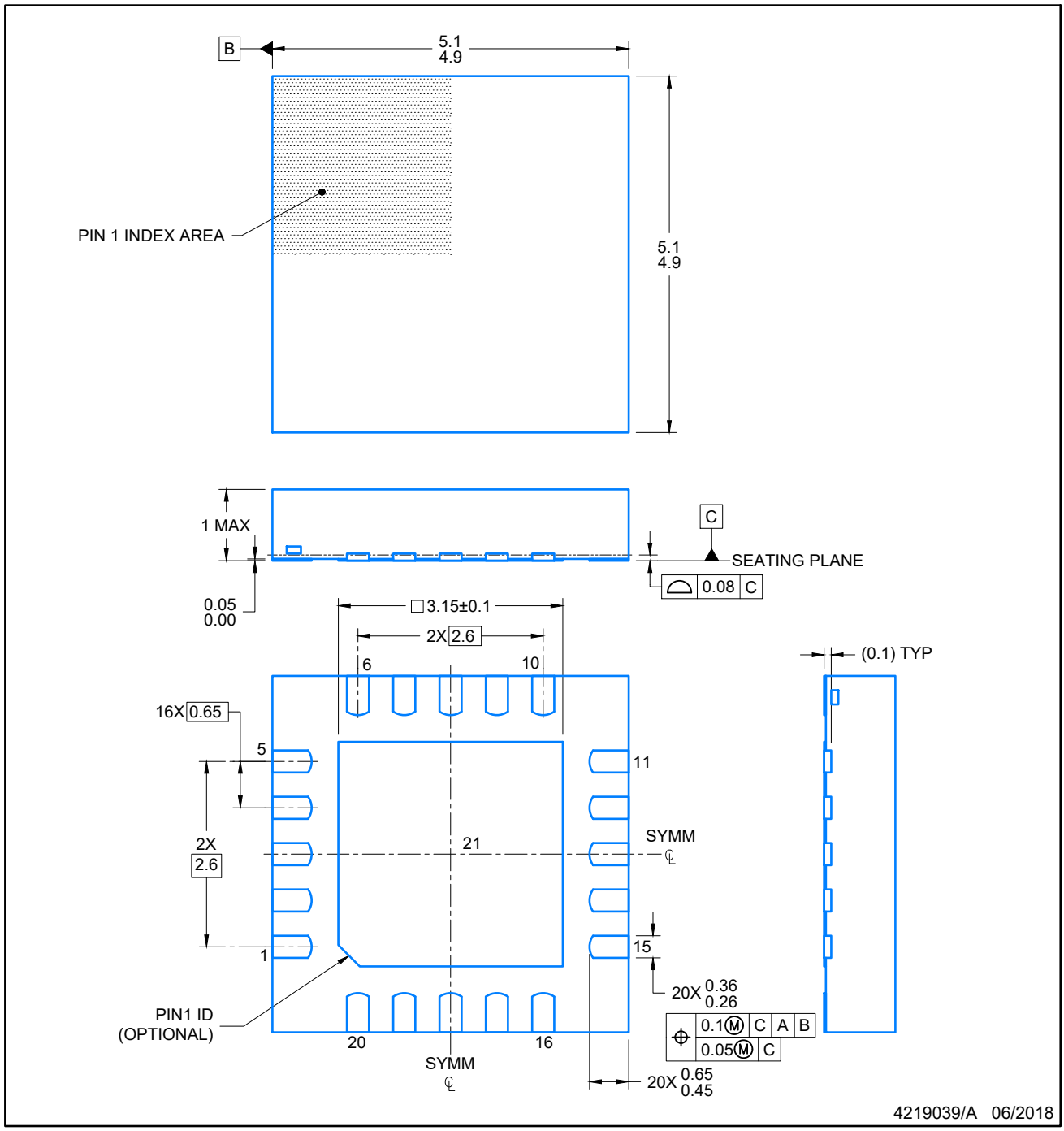
4227157/A

PACKAGE OUTLINE

RGW0020A

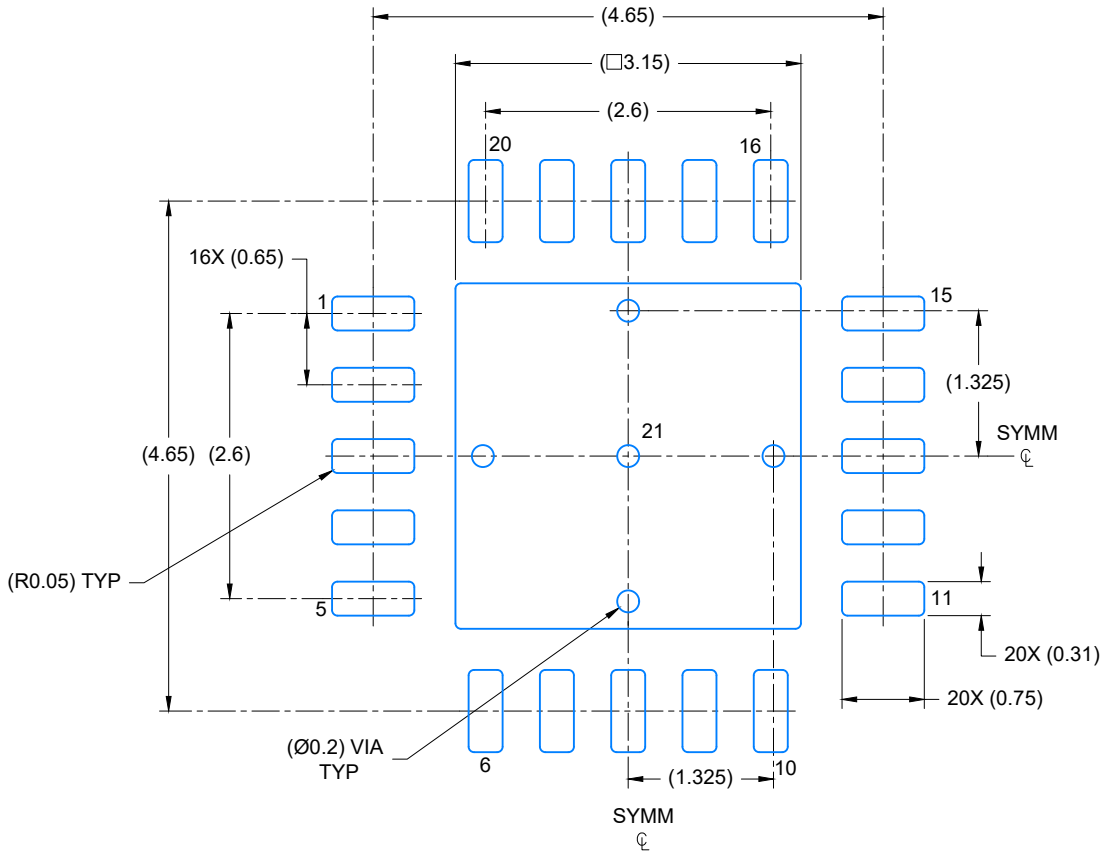
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK-NO LEAD



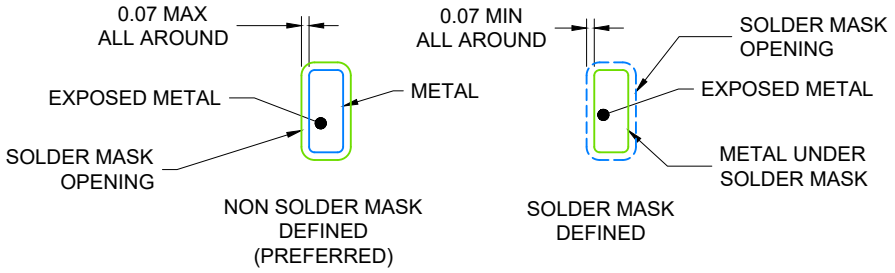
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



LAND PATTERN EXAMPLE

SCALE: 15X

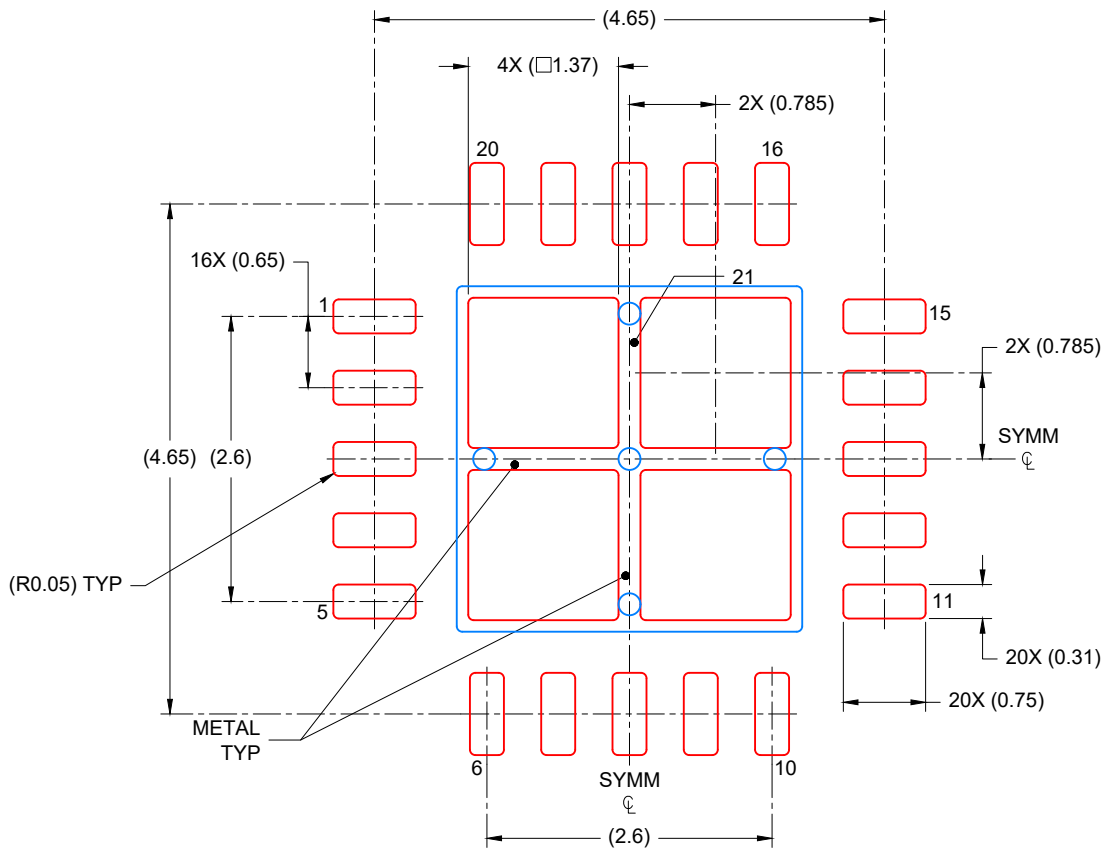


SOLDER MASK DETAILS

4219039/A 06/2018

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
75% PRINTED COVERAGE BY AREA
SCALE: 15X

4219039/A 06/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

GENERIC PACKAGE VIEW

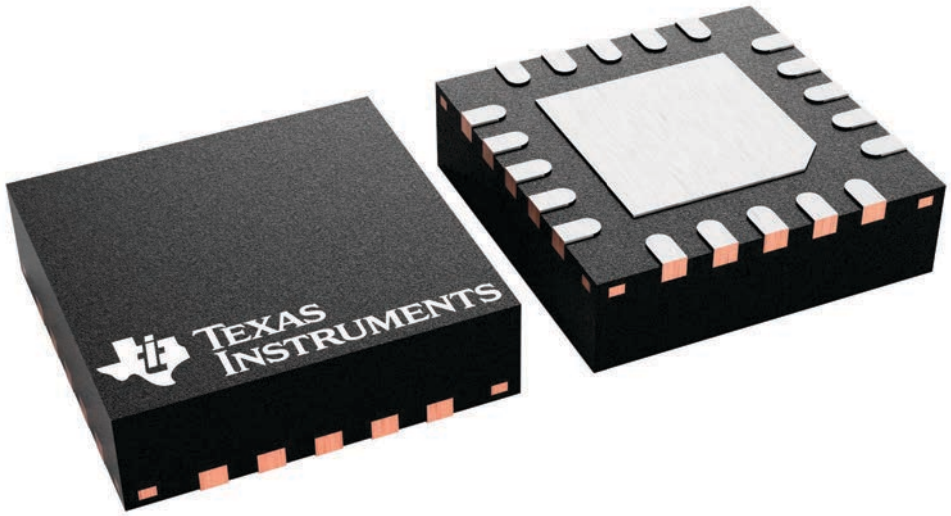
RGR 20

VQFN - 1 mm max height

3.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



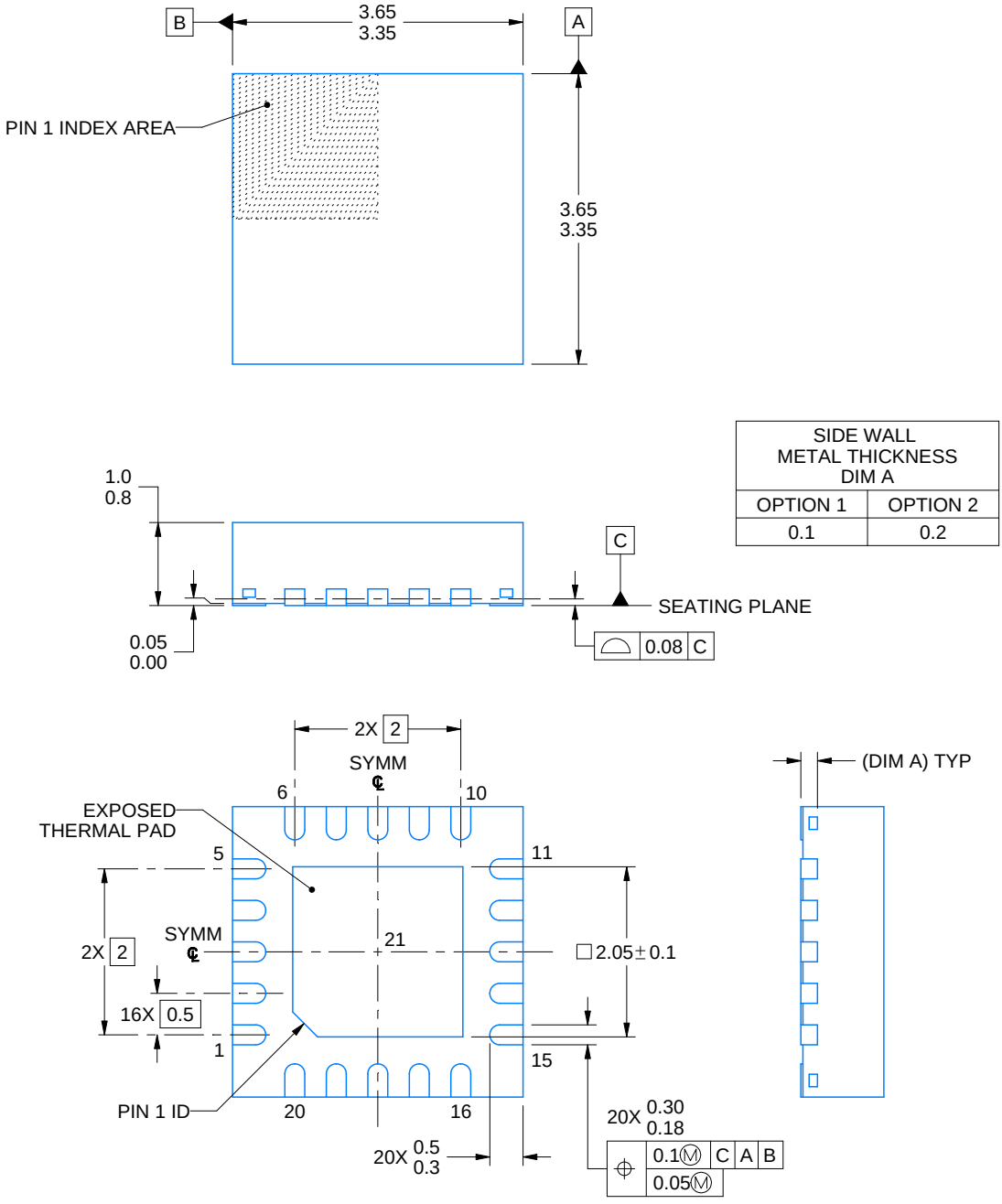
4228482/A

PACKAGE OUTLINE

RGR0020A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

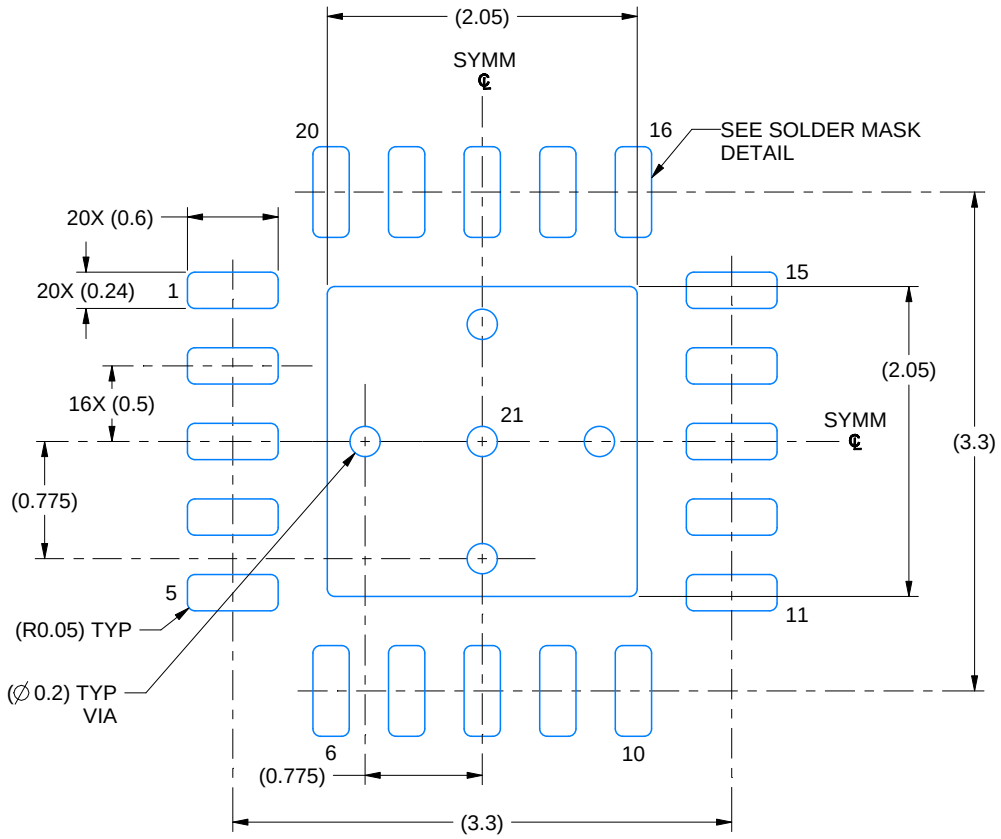


SIDE WALL METAL THICKNESS DIM A	
OPTION 1	OPTION 2
0.1	0.2

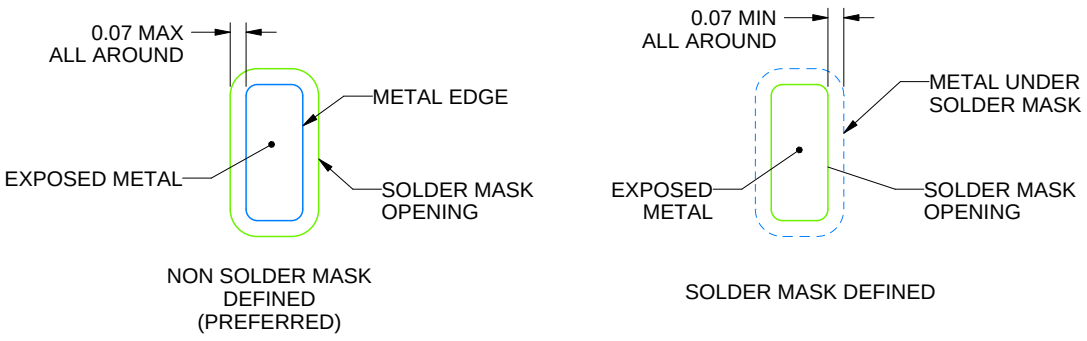
4219031/B 04/2022

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X

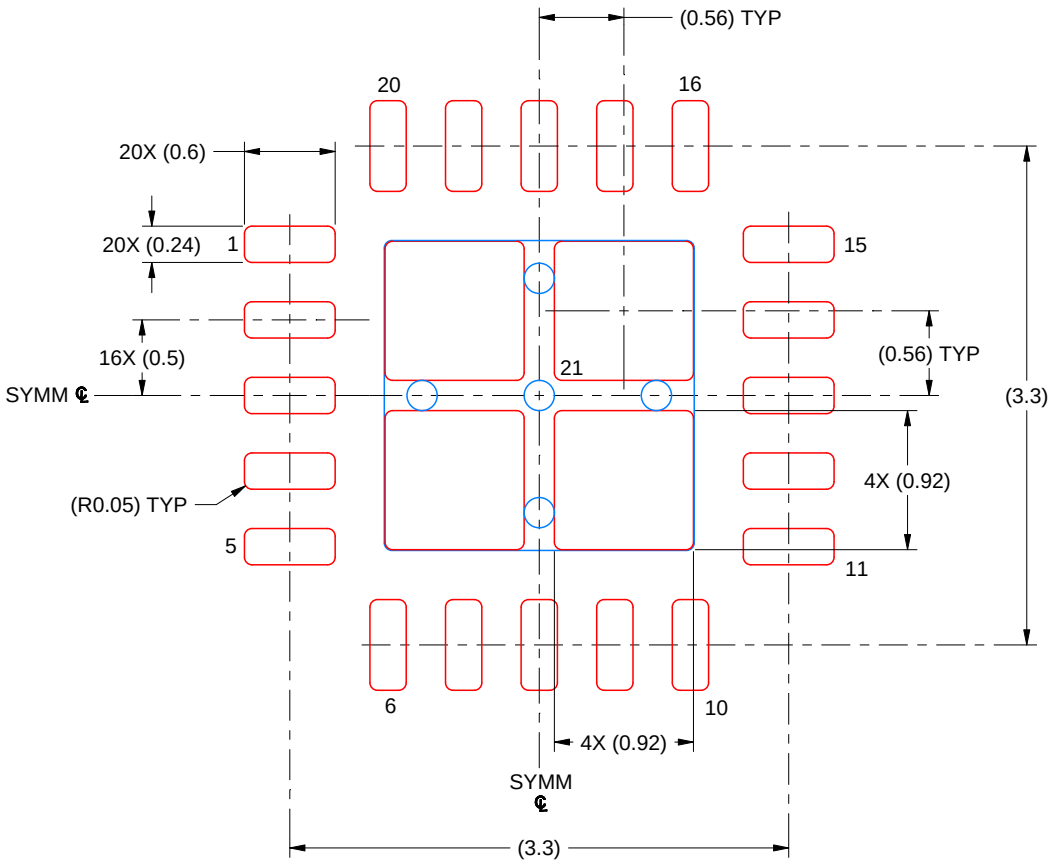


SOLDER MASK DETAILS

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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 20X

EXPOSED PAD 21
81% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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